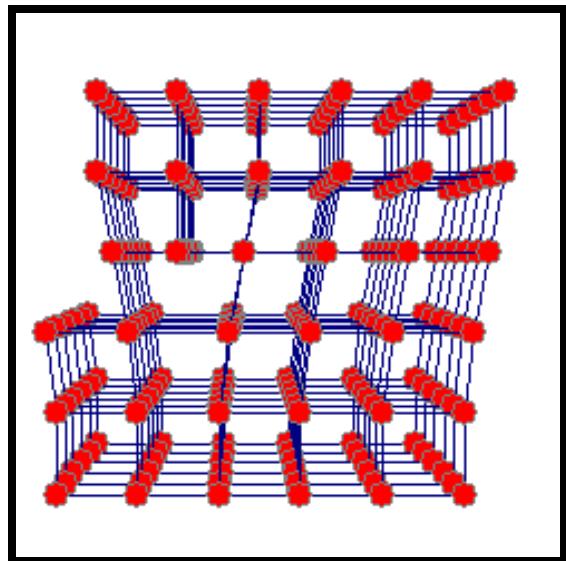
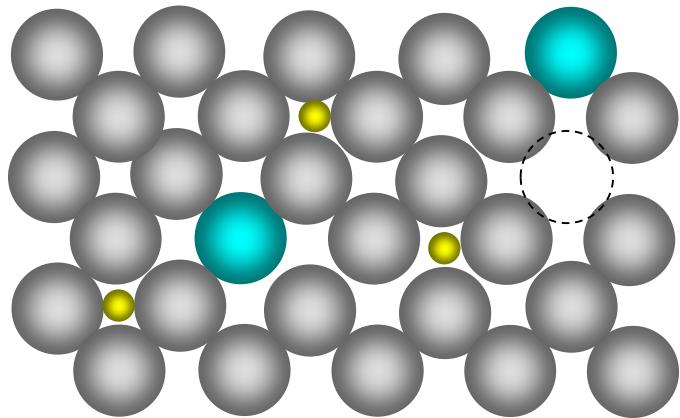


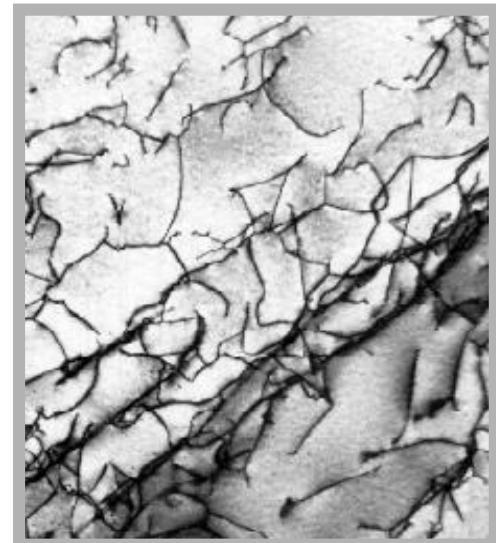
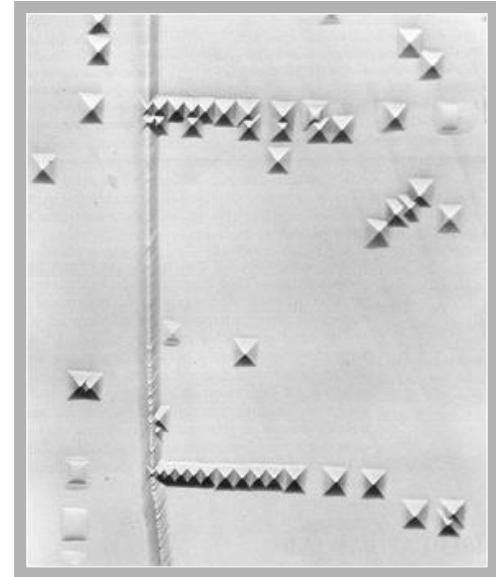
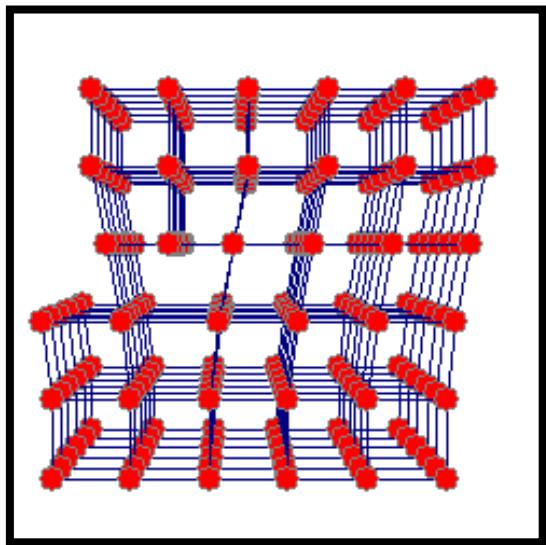
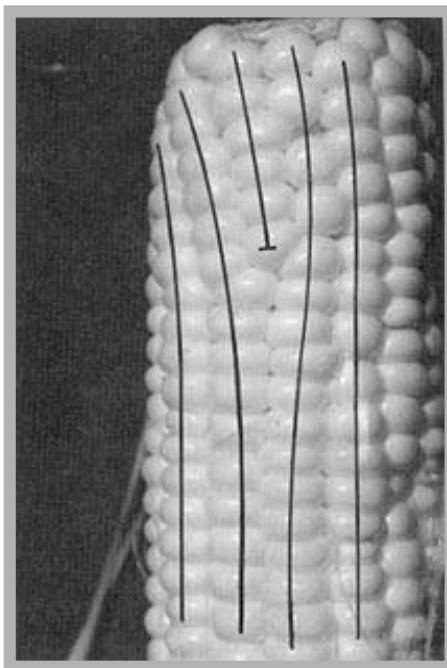
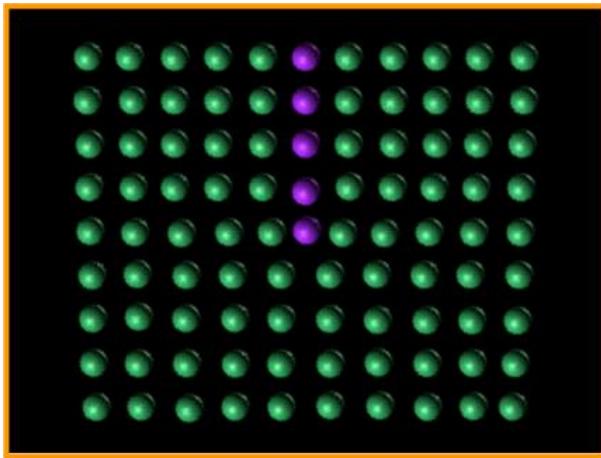
Chapter 4

4. Imperfections in Solids

- point defect
- diffusion
- line defect
- planar defect



Dislocations

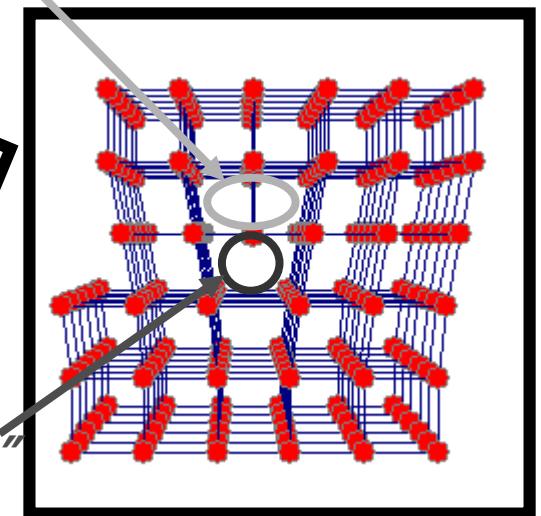
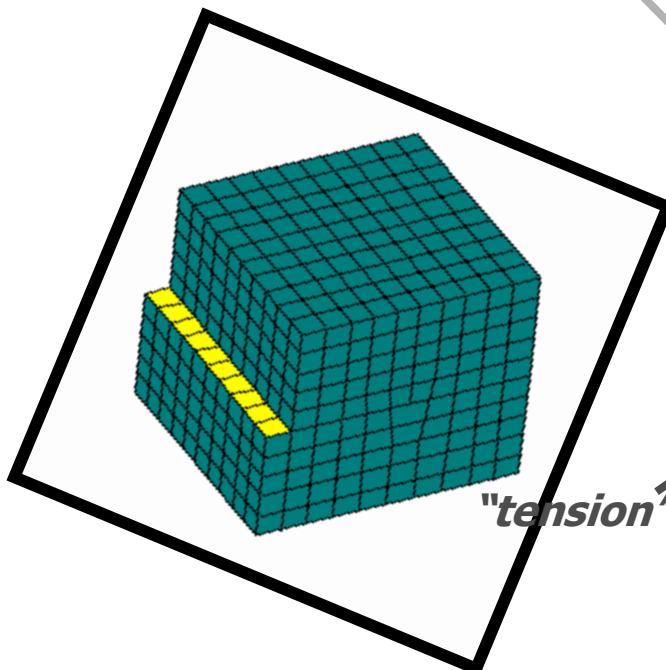
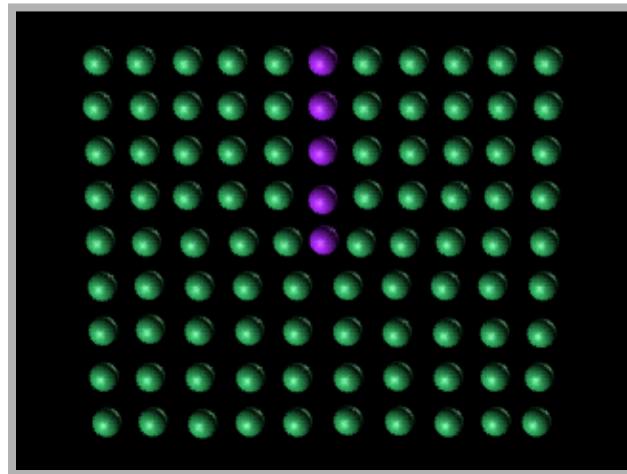
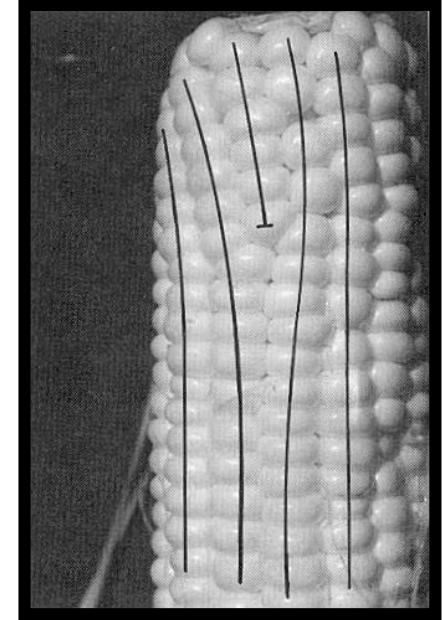


Types of Dislocations

□ Edge:

- extra half-plane inserted into an otherwise ideal lattice
- ↑ elastic distortion of the lattice
- severe distortion in the vicinity of the end point of inserted plane.
- Types: positive and negative

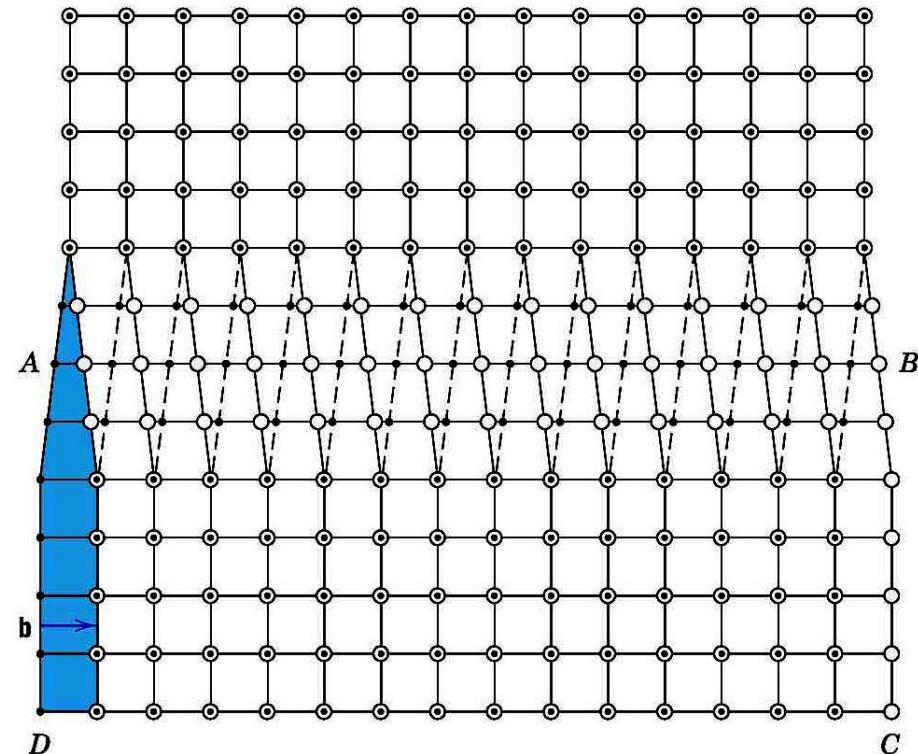
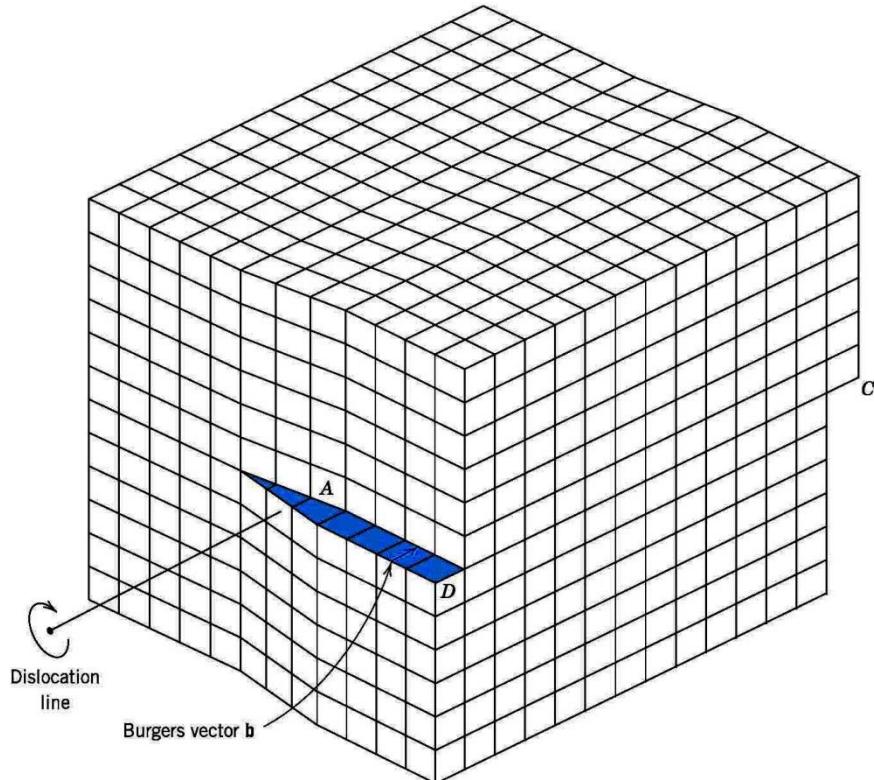
"compression"



Types of Dislocations

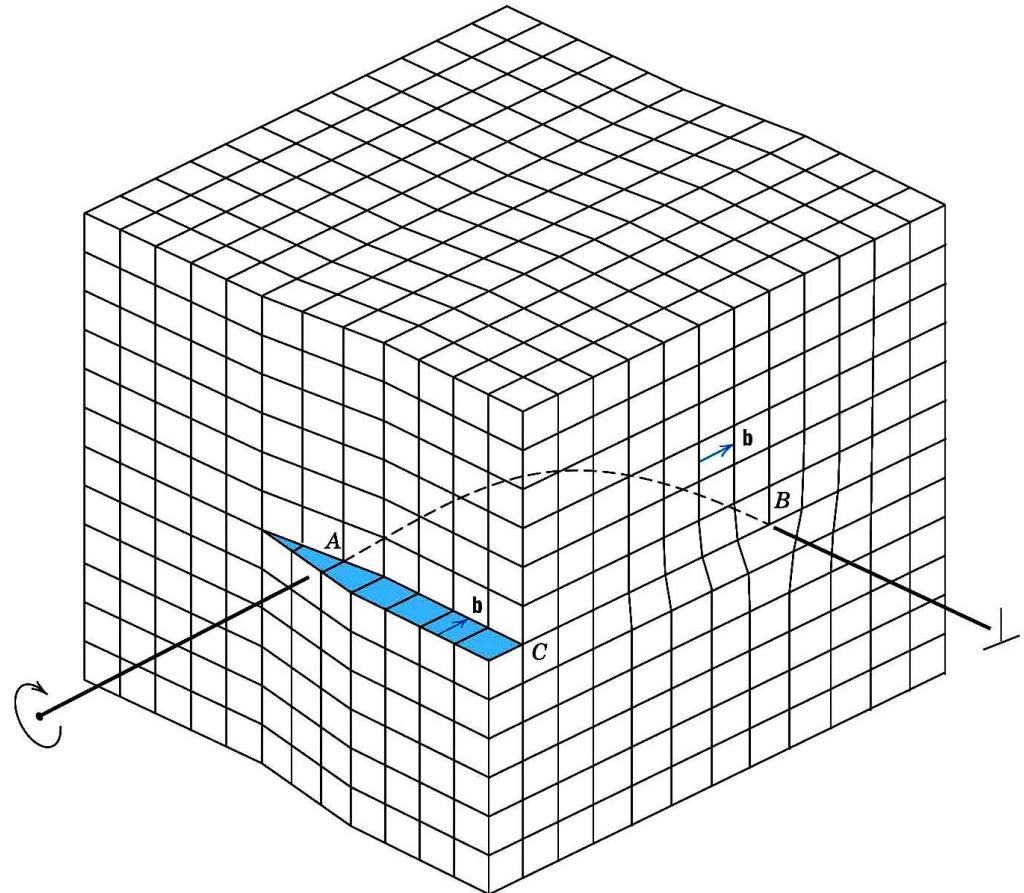
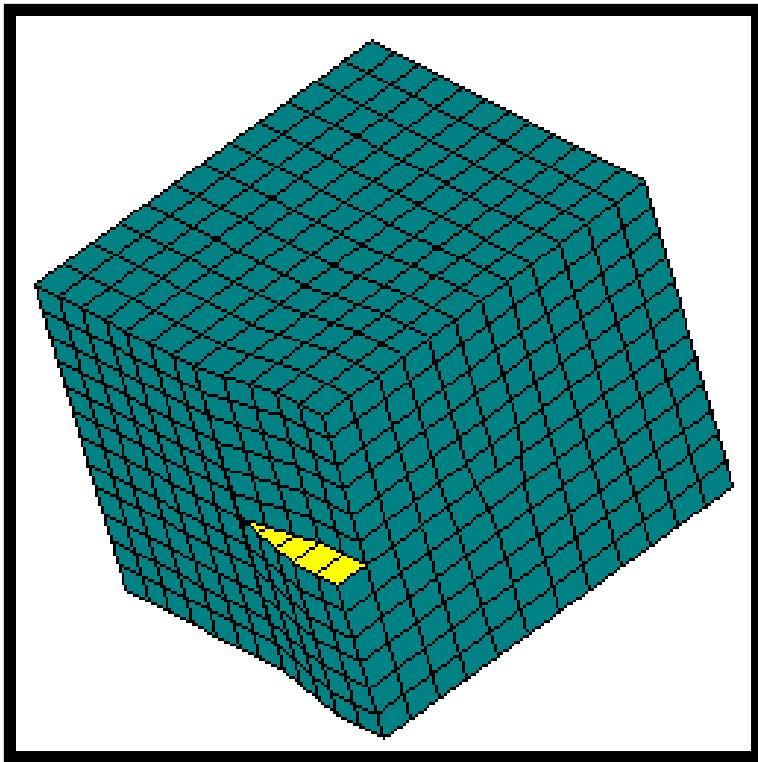
□ Screw:

- predominantly involved in the plastic deformation of BCC metals.
- Types: right hand side, and left hand side.



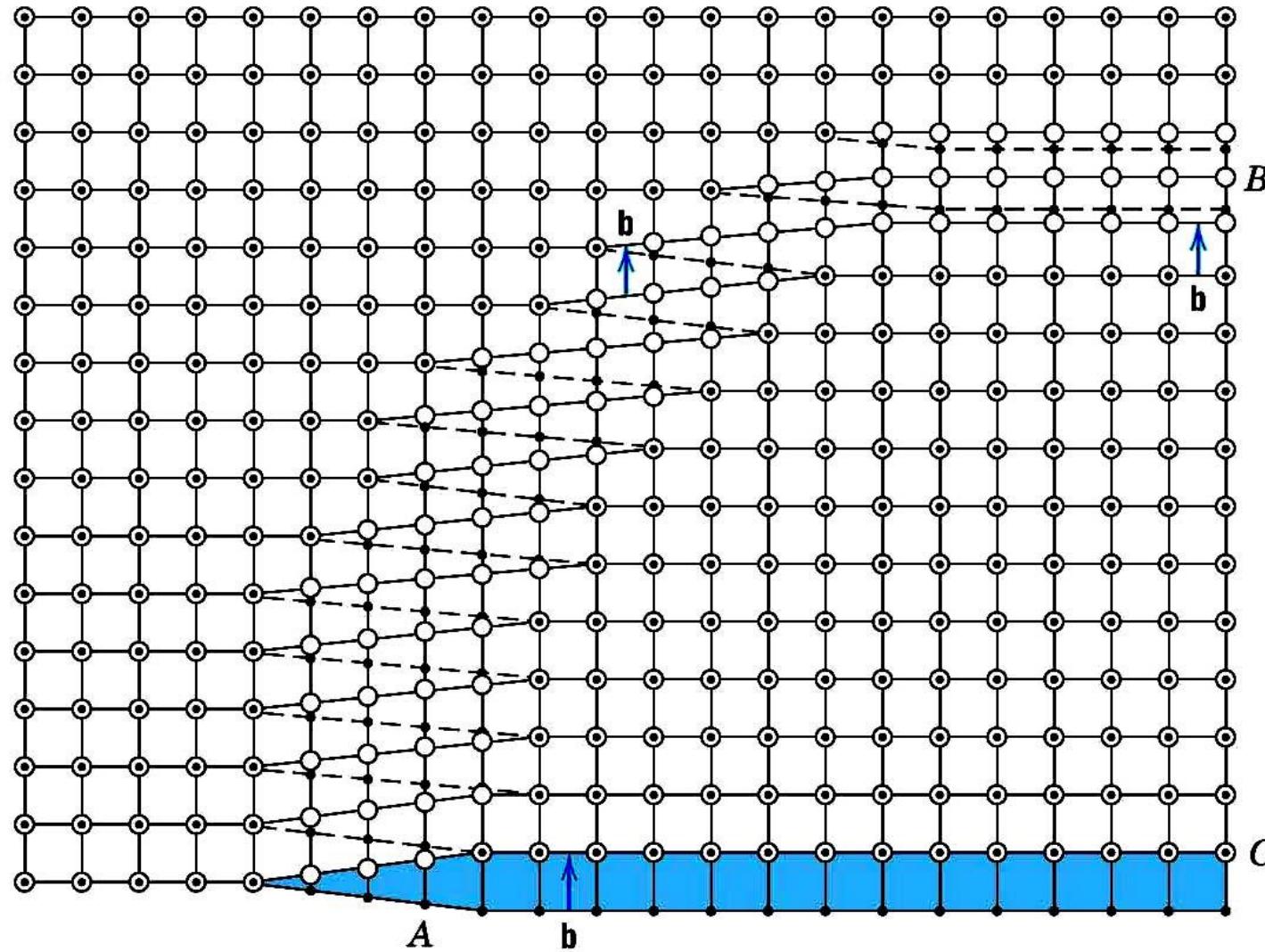
Types of Dislocations

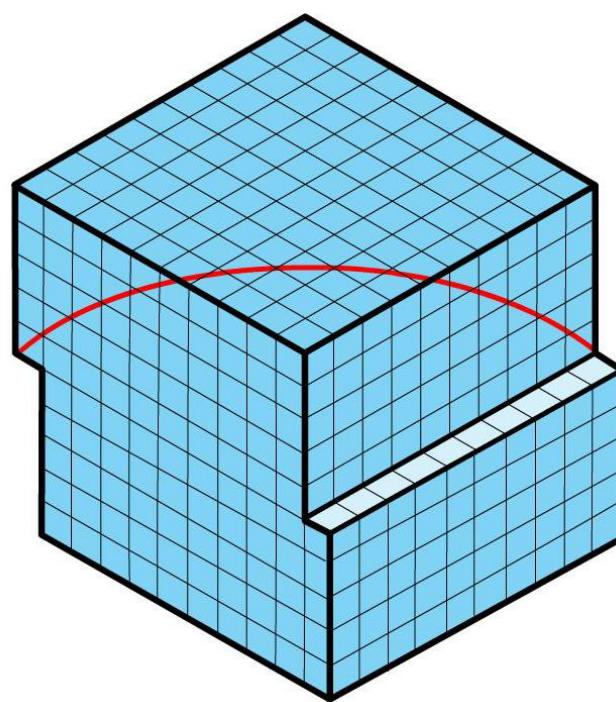
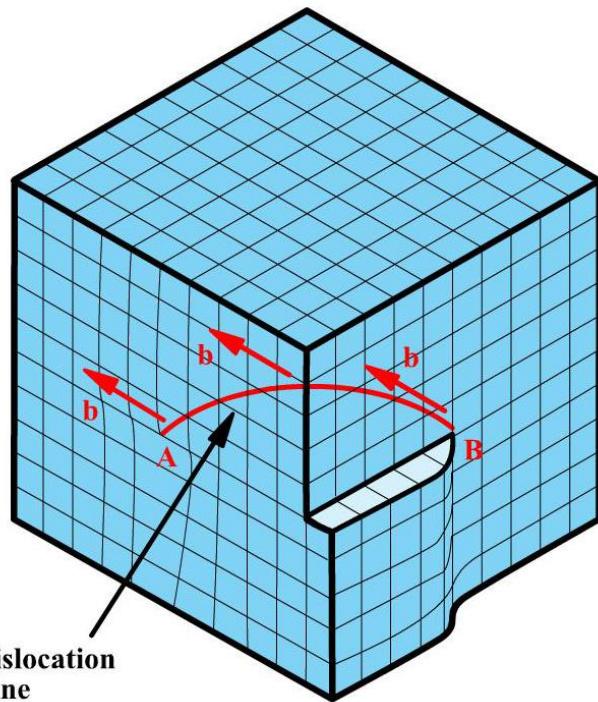
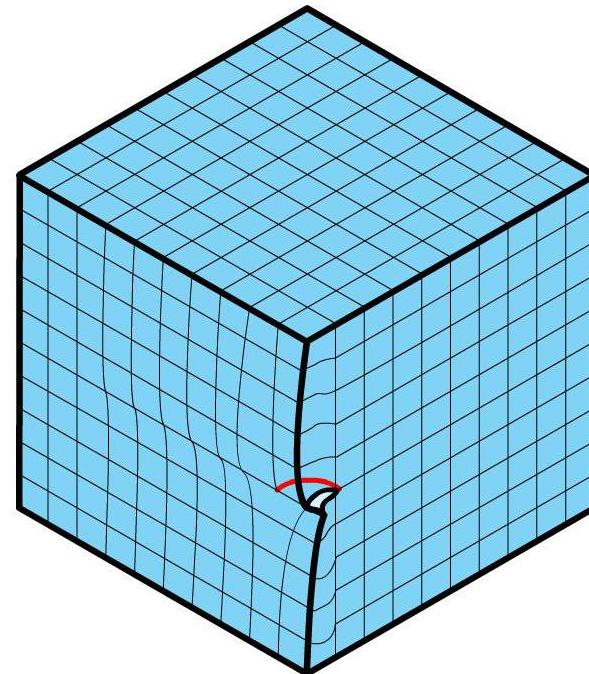
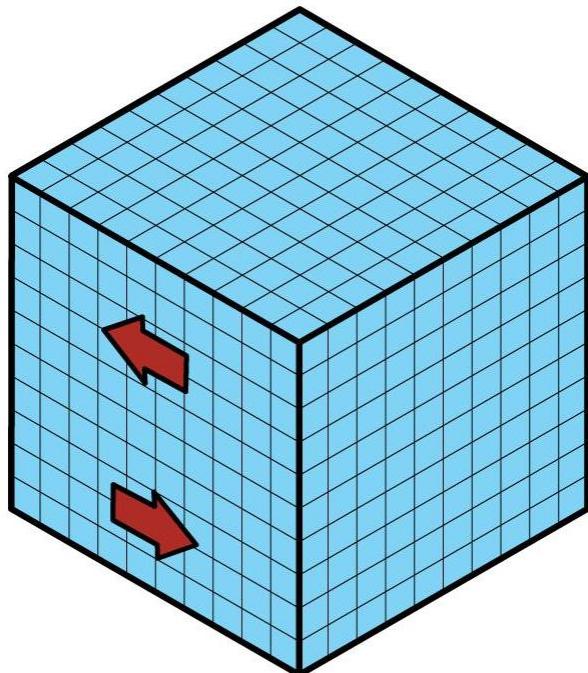
□ Mixed:



Mixed Dislocations

- open circle—atoms above slip plane
solid circle—atoms below slip plane



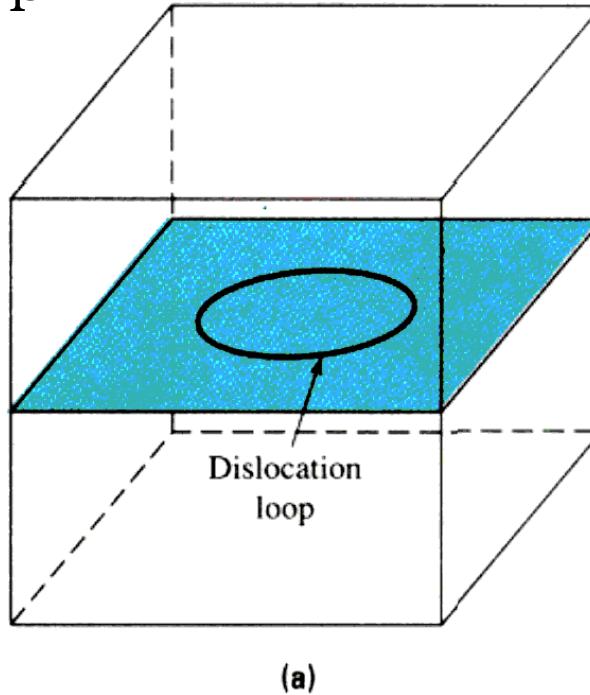


Types of Dislocations

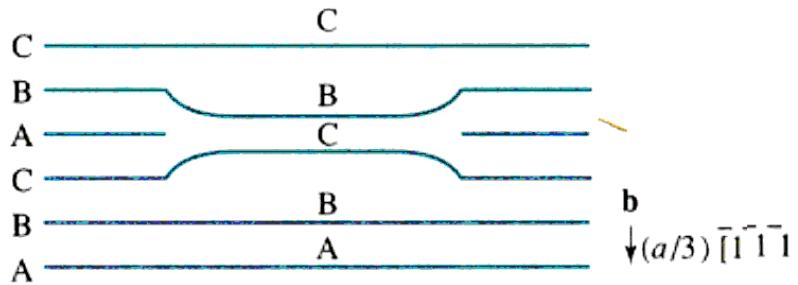
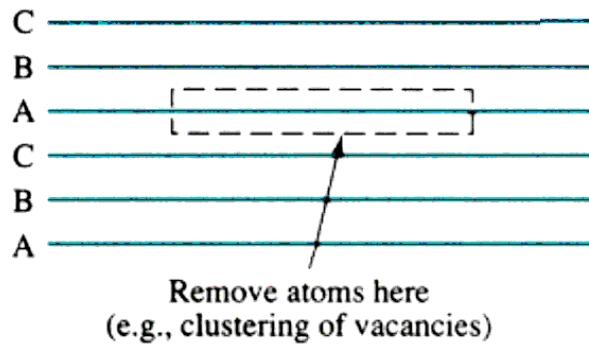
- since a dislocation line defines the boundary between one region of the crystal in which the slip already taken place and another which has not yet slipped, it follows that it cannot terminate within the crystal.
- a dislocation line can form a closed dislocation loop, or its two ends can terminate at the surface of the crystal.
- dislocation loops are common

Types of Dislocations

- Dislocation loop:

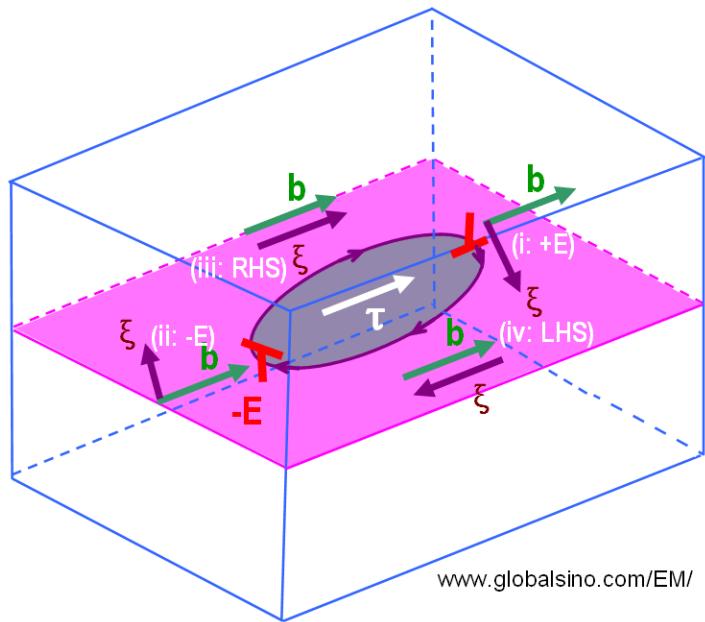


(a)



Types of Dislocations

□ Dislocation loop:



www.globalsino.com/EM/

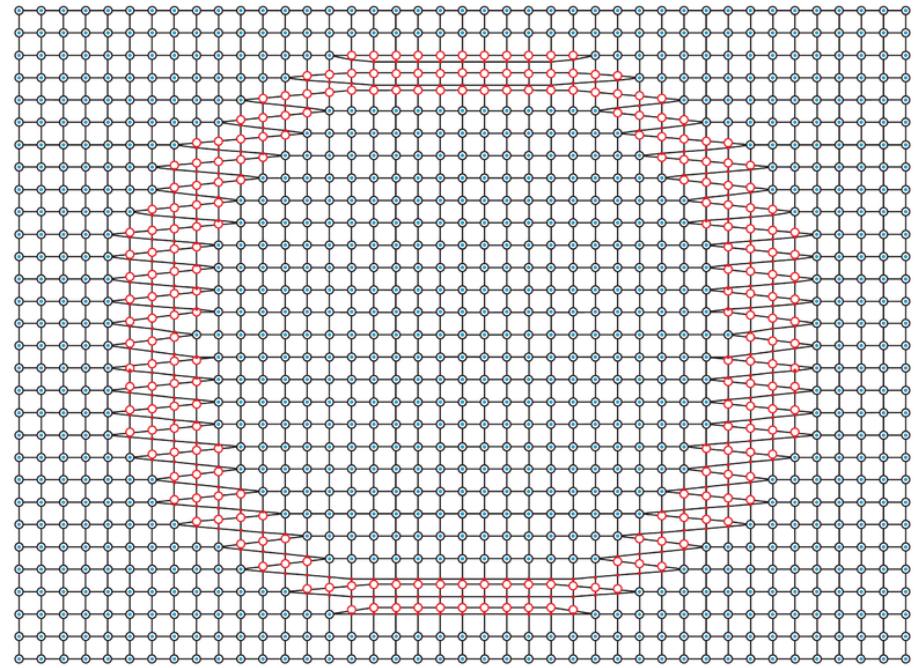


Figure 3454. Glide and dislocation loops.

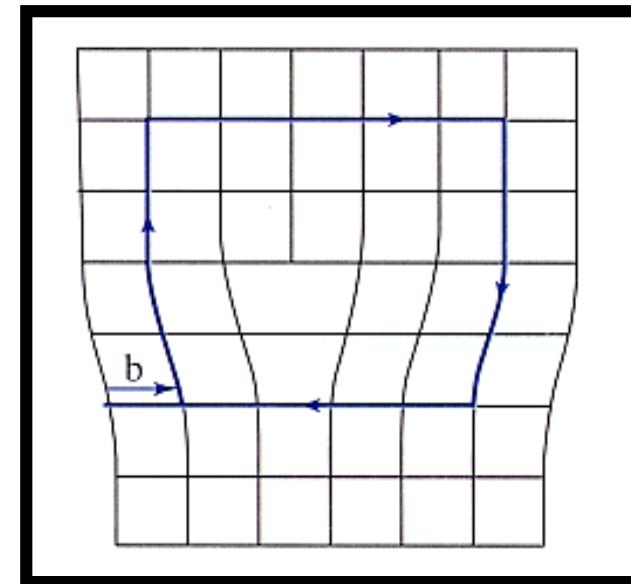
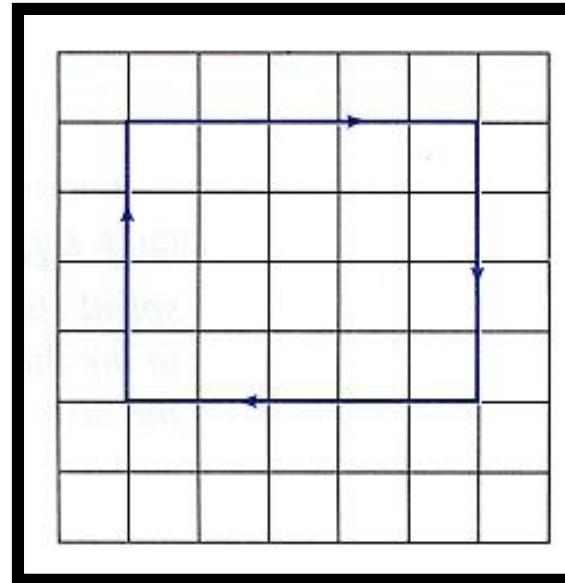
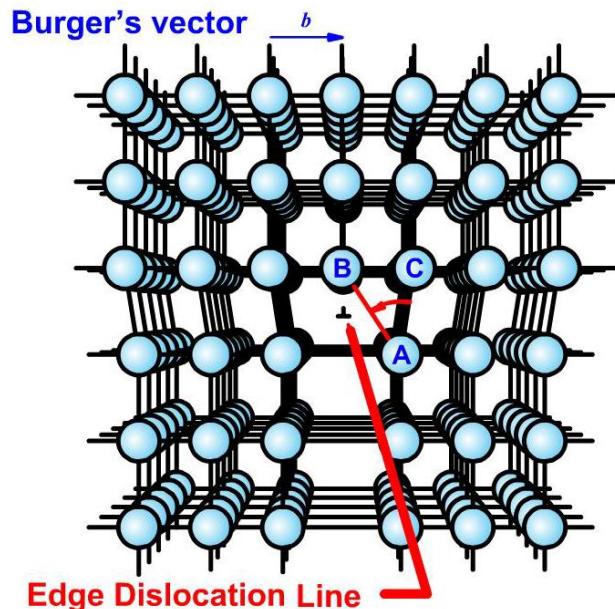
<https://www.globalsino.com/EM/page3454.html>

https://commons.wikimedia.org/wiki/File:Dislocation_loop.png

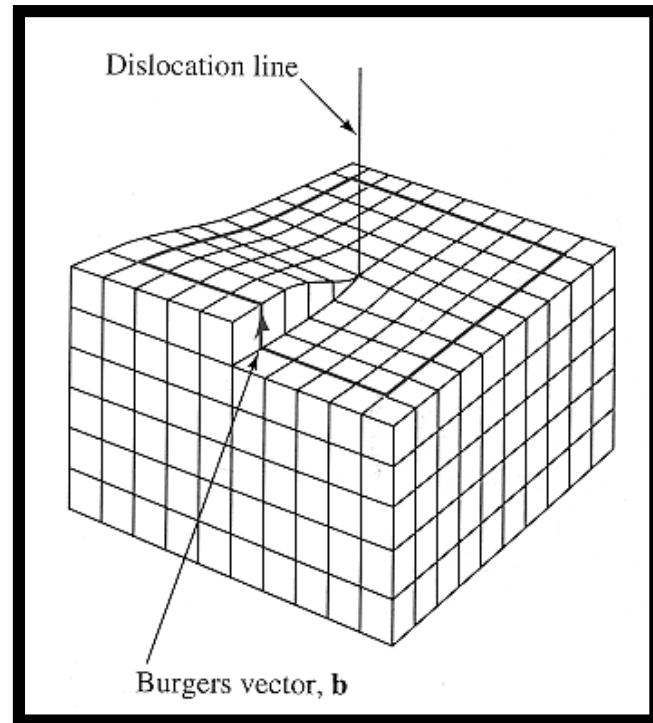
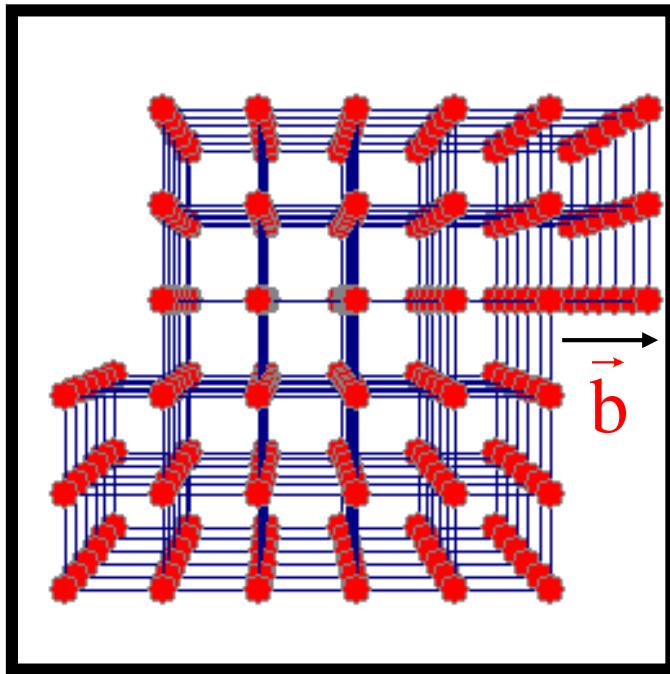
Characterization of Dislocations

□ Burgers vector: \vec{b}

- expresses the magnitude and direction of the main lattice distortion.
- it is always **parallel** to the *slip* direction
- dislocation line.



Characterization of Dislocations



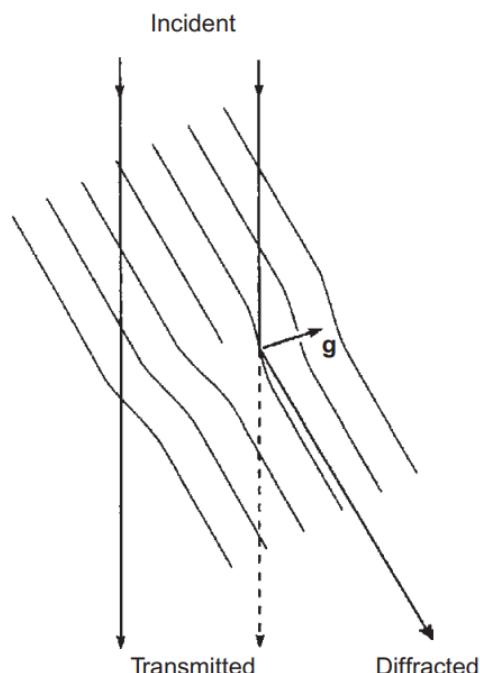
edge dislocation- $\vec{b} \perp$ dislocation line

screw dislocation- $\vec{b} \parallel$ dislocation line

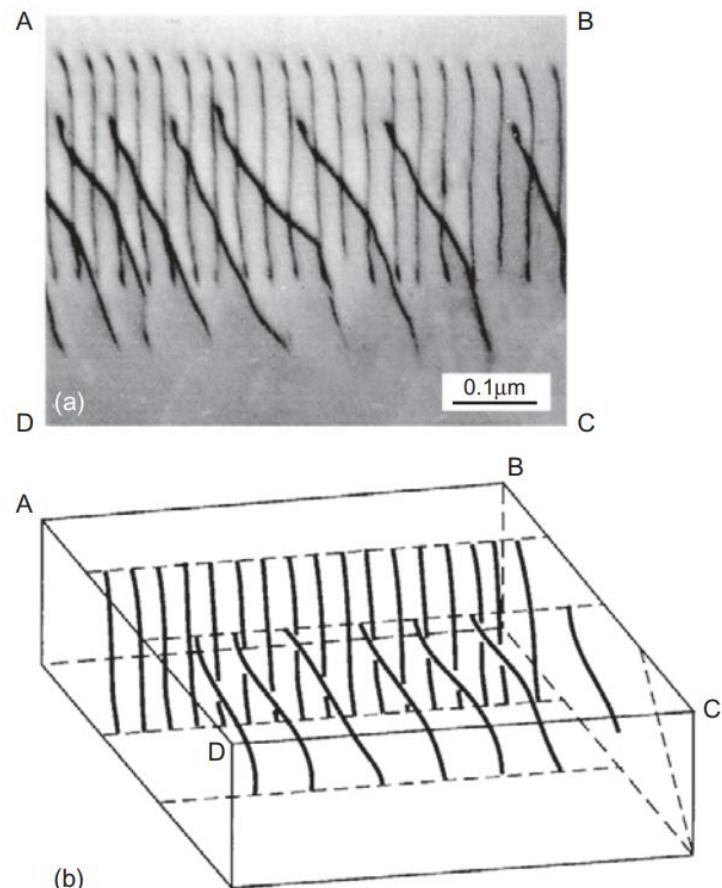
Observing Dislocations

- **Etch pits** - Tiny holes created at areas where dislocations meet the surface. These are used to examine the presence and number density of dislocations.
- **Slip line** - A visible line produced at the surface of a metallic material by the presence of several thousand dislocations.
- **Slip band** - Collection of many slip lines, often easily visible.

Observing Dislocations



Planes near an edge dislocation bent into the orientation for diffraction.



(a) Thin film transmission electron micrograph showing two parallel rows of dislocations. Each dark line is produced by a dislocation. The dislocations extend from top to bottom of the foil which is about 200 nm thick. (b) The line diagram illustrates the distribution of the dislocations in the foil and demonstrates that the photograph above represents a projected image of a three-dimensional array of dislocations

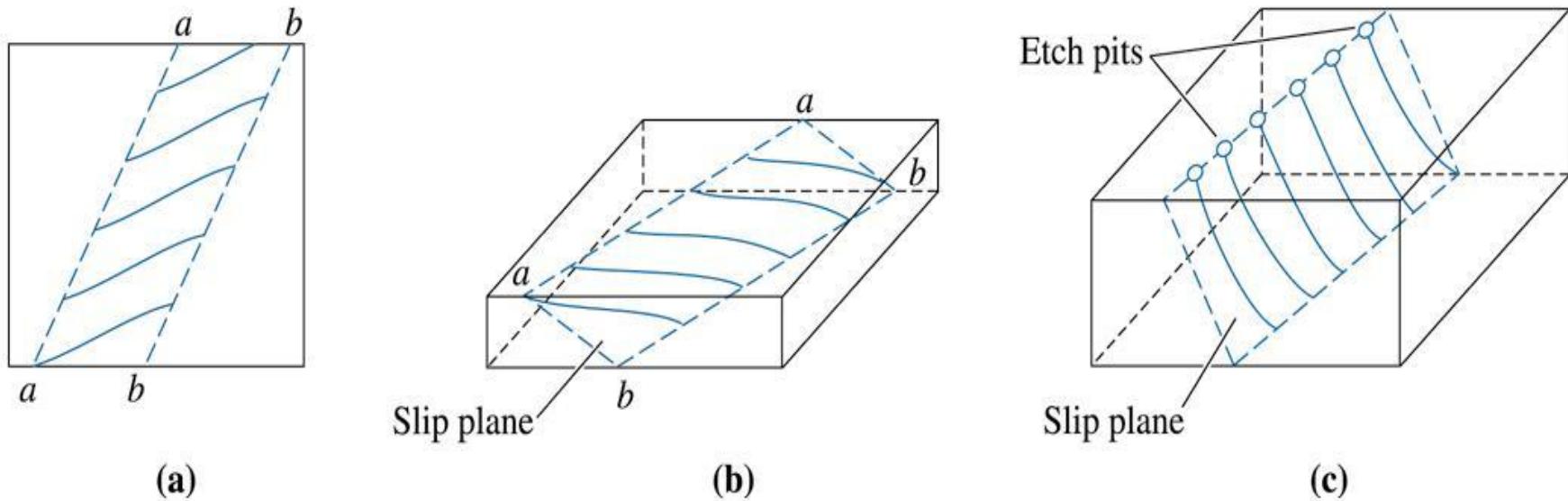
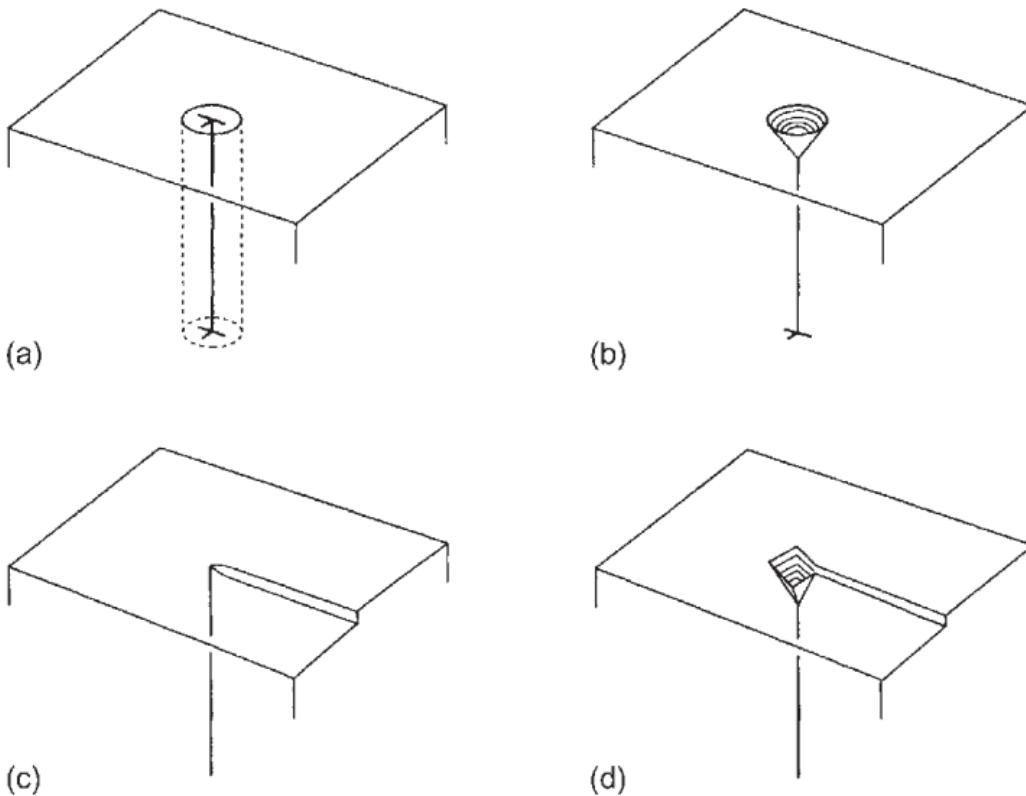


Figure 4.11 A sketch illustrating dislocations, slip planes, and etch pit locations. (*Source: Adapted from Physical Metallurgy Principles, Third Edition, by R.E. Reed-Hill and R. Abbaschian, p. 92, Figs. 4-7 and 4-8. Copyright (c) 1992 Brooks/Cole Thomson Learning. Adapted by permission.*)



Formation of etch pits at the site where a dislocation meets the surface. (a) Edge dislocation, the cylindrical zone around the dislocation represents the region of the crystal with different physical and chemical properties from the surrounding crystal. (b) Conical-shaped pit formed at an edge dislocation due to preferential removal of atoms from the imperfect region. (c) Emergent site of a screw dislocation. (d) Spiral pit formed at a screw dislocation; the pits form by the reverse process to the crystal growth mechanism.

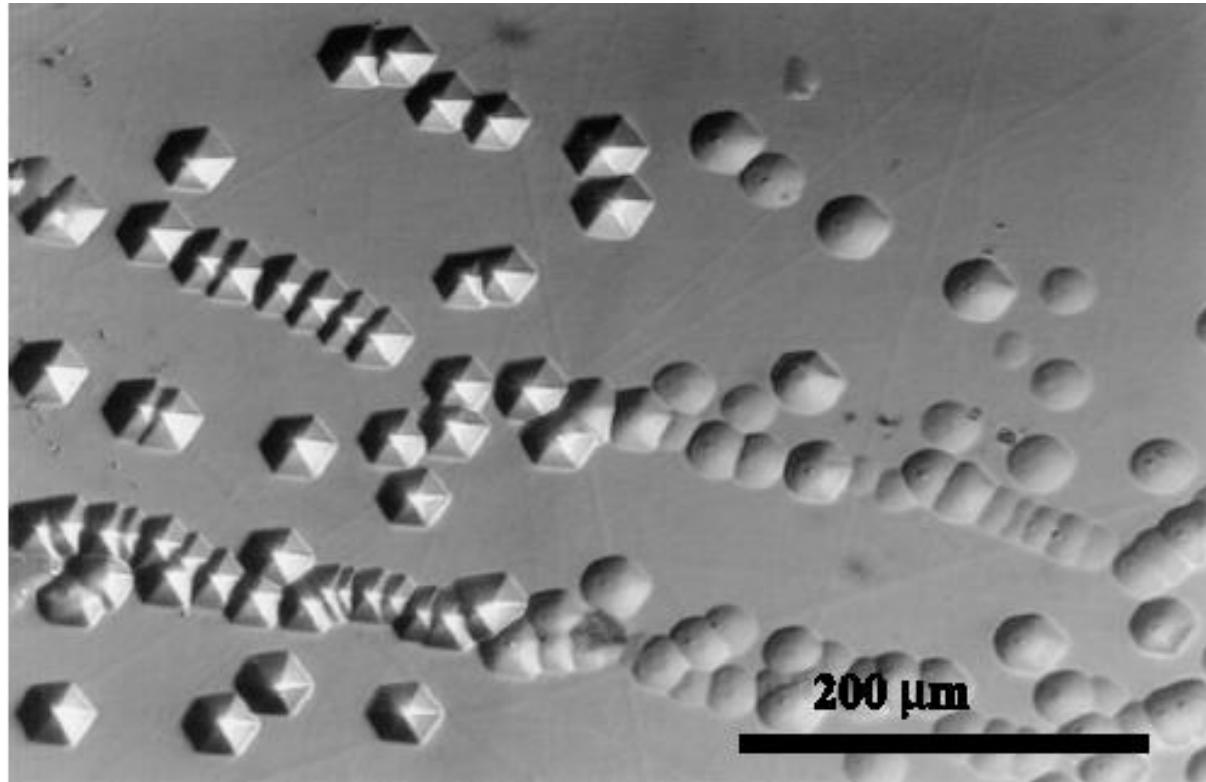


Figure 4.12 Optical image of etch pits in silicon carbide (SiC). The etch pits correspond to intersection points of pure edge dislocations with Burgers vector $a/3 \langle 1\bar{1}20 \rangle$ and the dislocation line direction along [0001] (perpendicular to the etched surface). Lines of etch pits represent low angle grain boundaries (*Courtesy of Dr. Marek Skowronski, Carnegie Mellon University.*)

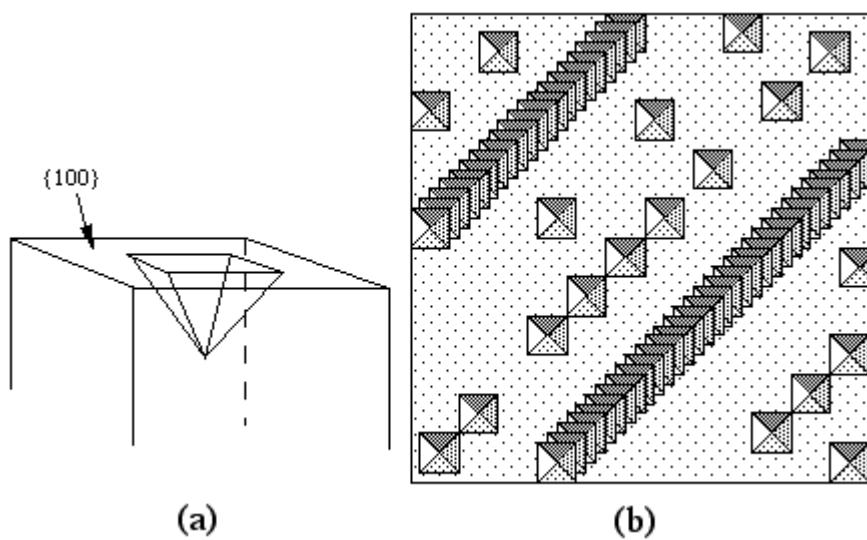
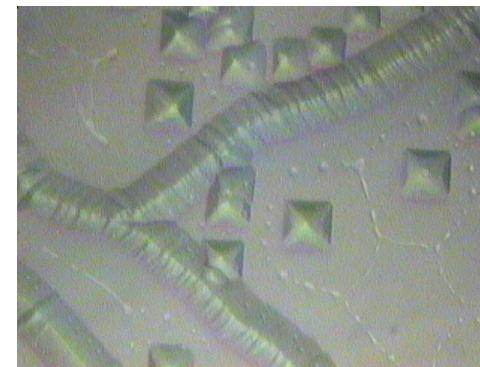
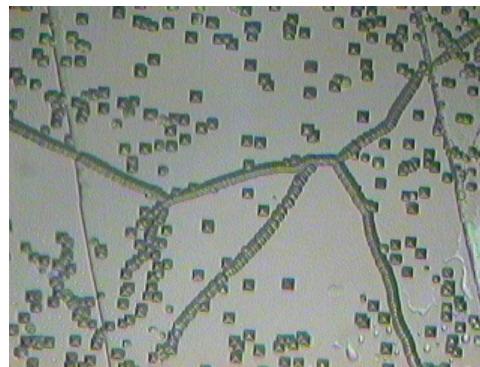
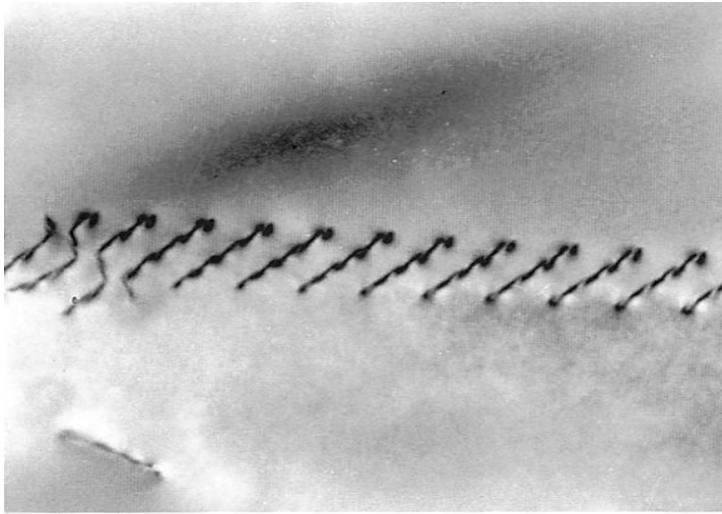


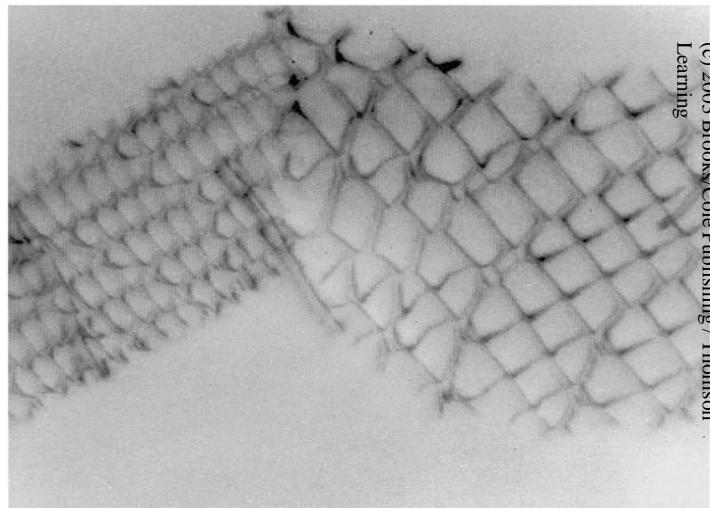
Figure 5. Dislocation etch pits. (a) a three dimensional view of a pit with square pyramidal facets. (b) Projection showing schematic distribution on the surface.



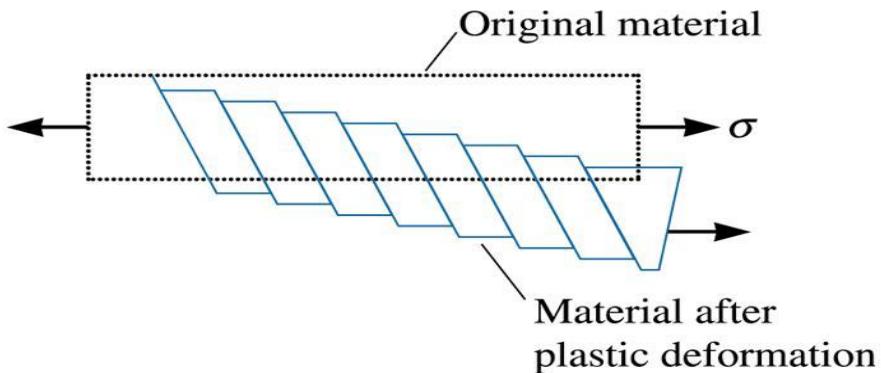
The following micrographs illustrate typical dislocation etch pits on cleaved rock salt surfaces



(a)



(b)



(c)

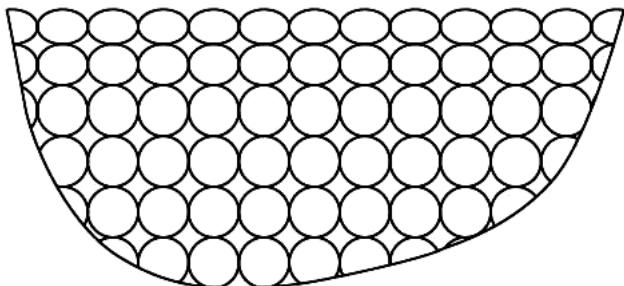
(c)2003 Brooks/Cole, a division of Thomson Learning, Inc. Thomson Learning™ is a trademark used herein under license.

Figure 4.13 Electron photomicrographs of dislocations in Ti_3Al : (a) Dislocation pileups ($\times 26,500$). (b) Micrograph at $\times 100$ showing slip lines and grain boundaries in Al. (c) Schematic of slip bands development.

Planar Defects

- surface
- twin boundary
- stacking fault
- grain boundary
- domain boundary

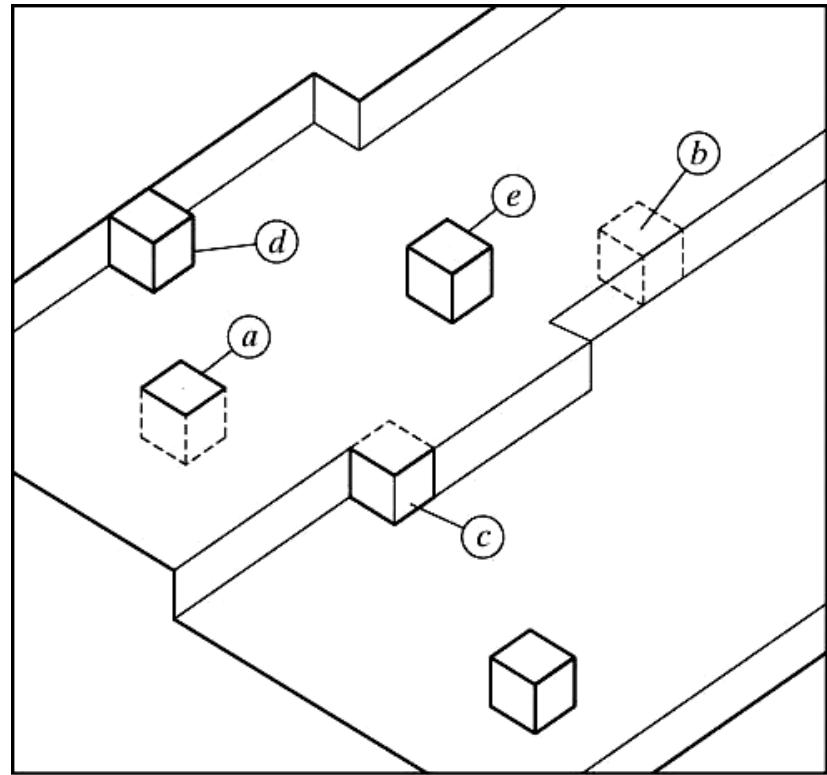
Surface



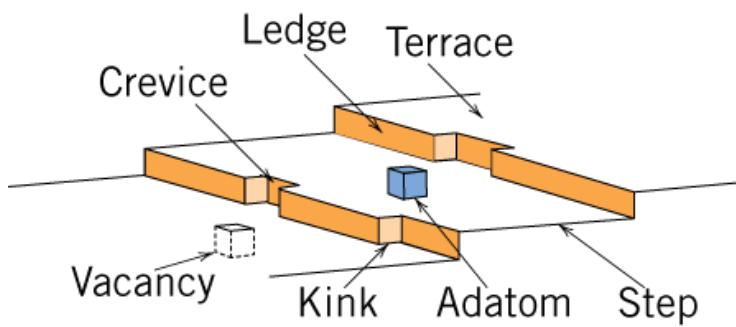
fewer nearest neighbor
Higher energy- surface
tension or energy



crystal growth from vapor phase
around a screw dislocation in SiC

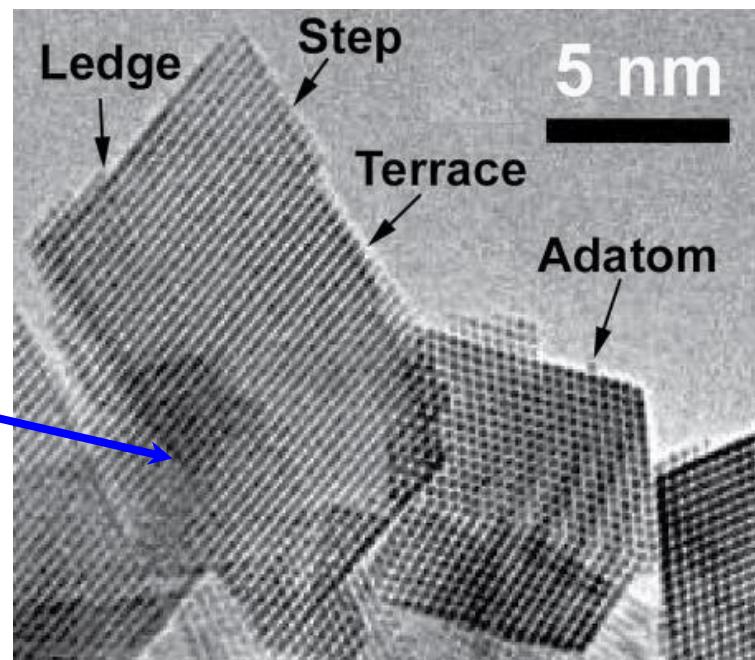


Hirth Pound model
ledge & kink

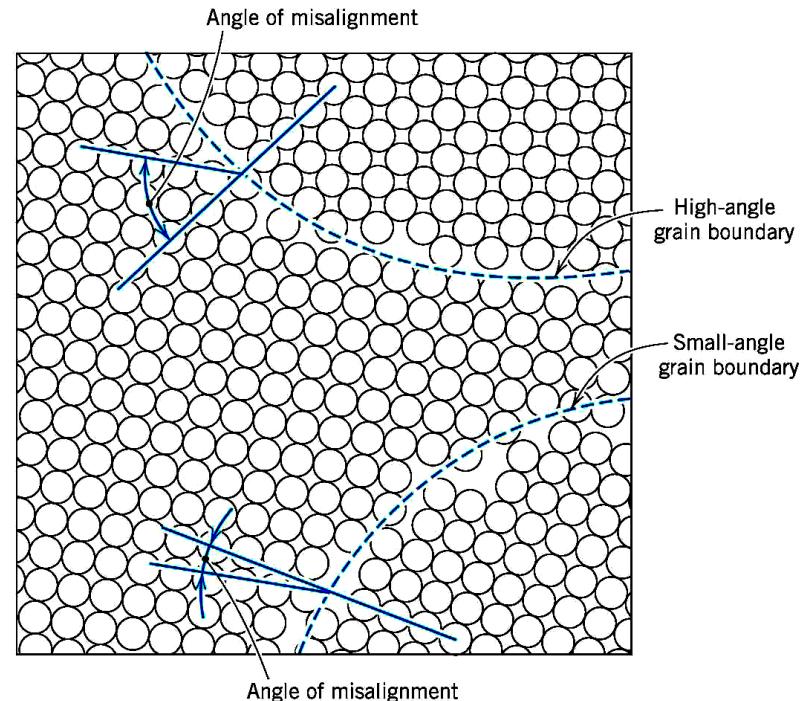
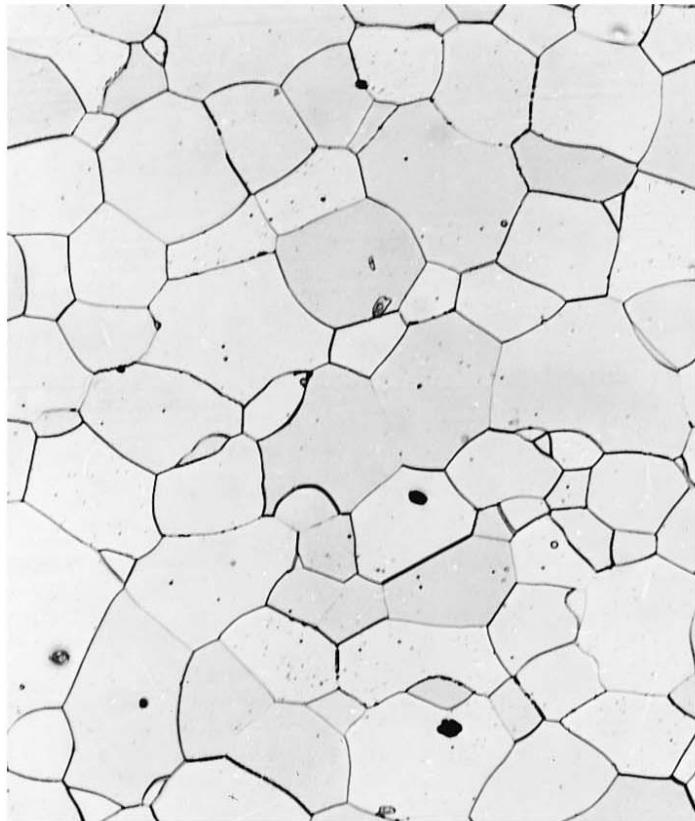


Single crystals of
 $(Ce_{0.5}Zr_{0.5})O_2$
 used in an automotive
 catalytic converter

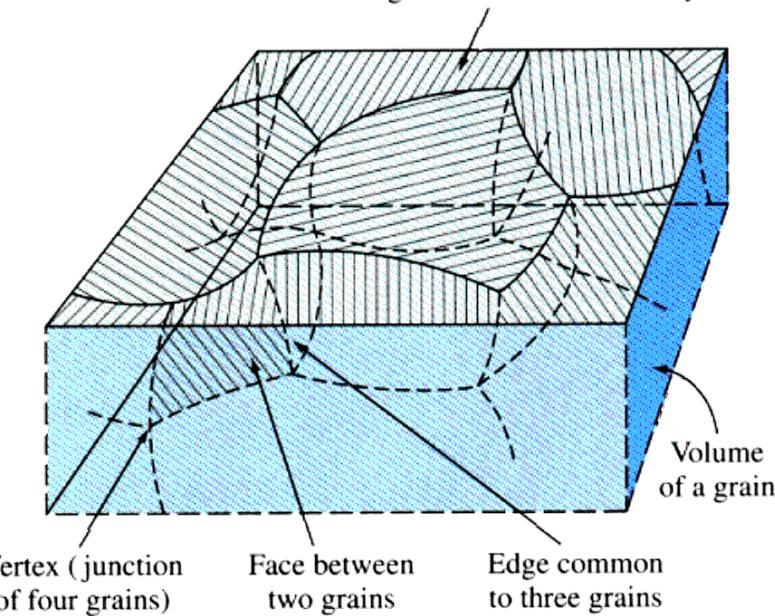
Fig. 4.12, Callister & Rethwisch 10e.
 [From W. J. Stark, L. Mädler, M. Maciejewski, S. E. Pratsinis, and A. Baiker, "Flame Synthesis of Nanocrystalline Ceria/Zirconia: Effect of Carrier Liquid," Chem. Comm., 588–589 (2003). Reproduced by permission of The Royal Society of Chemistry.]



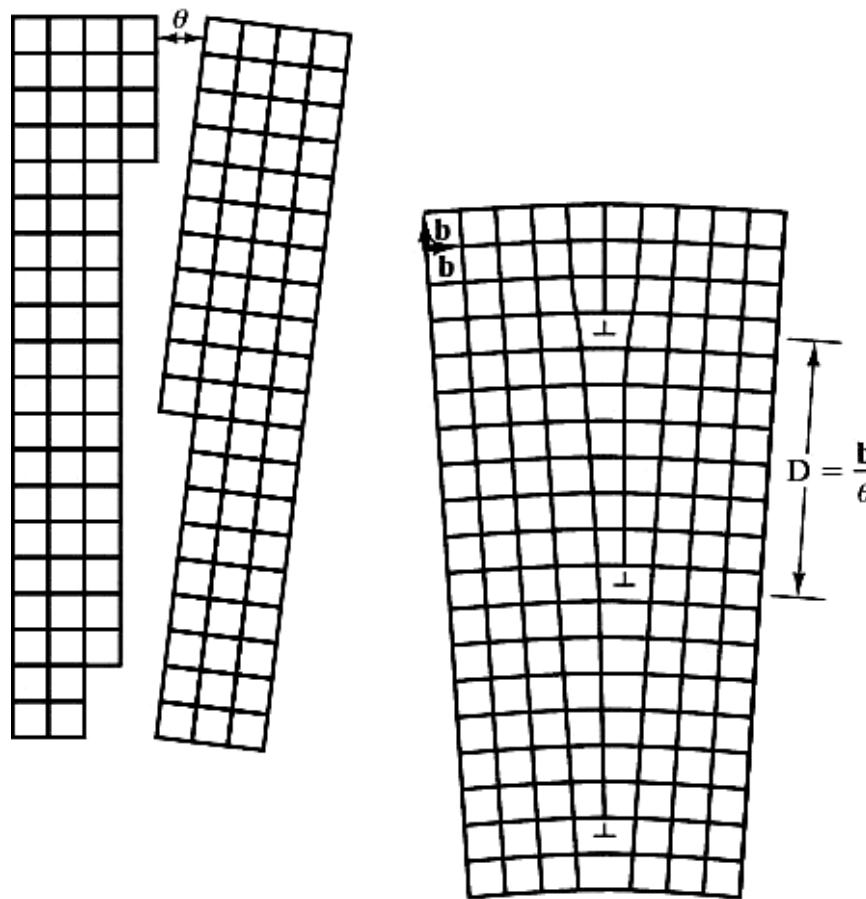
Grain Boundary



Microstructure on top surface.
Each grain shaded distinctively

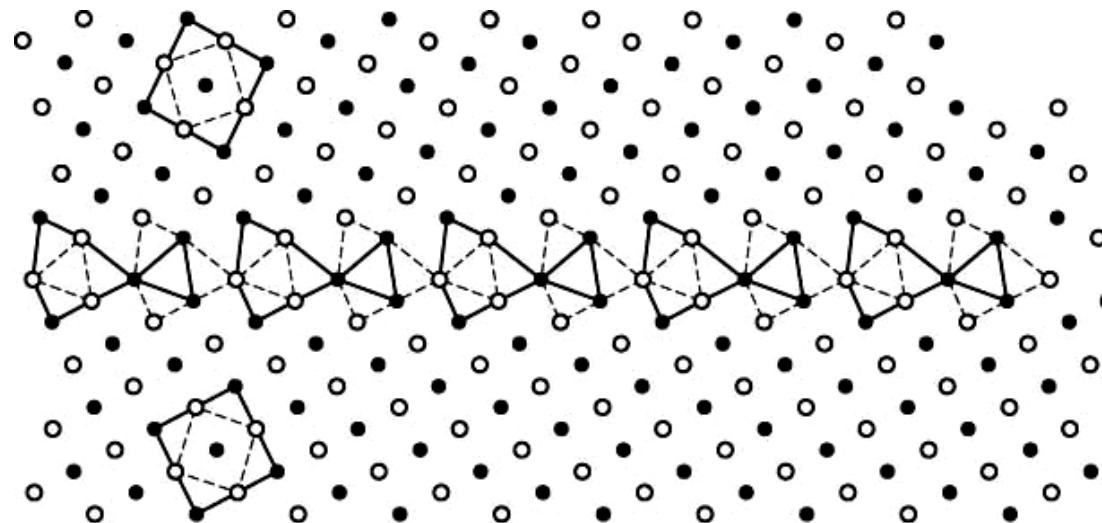
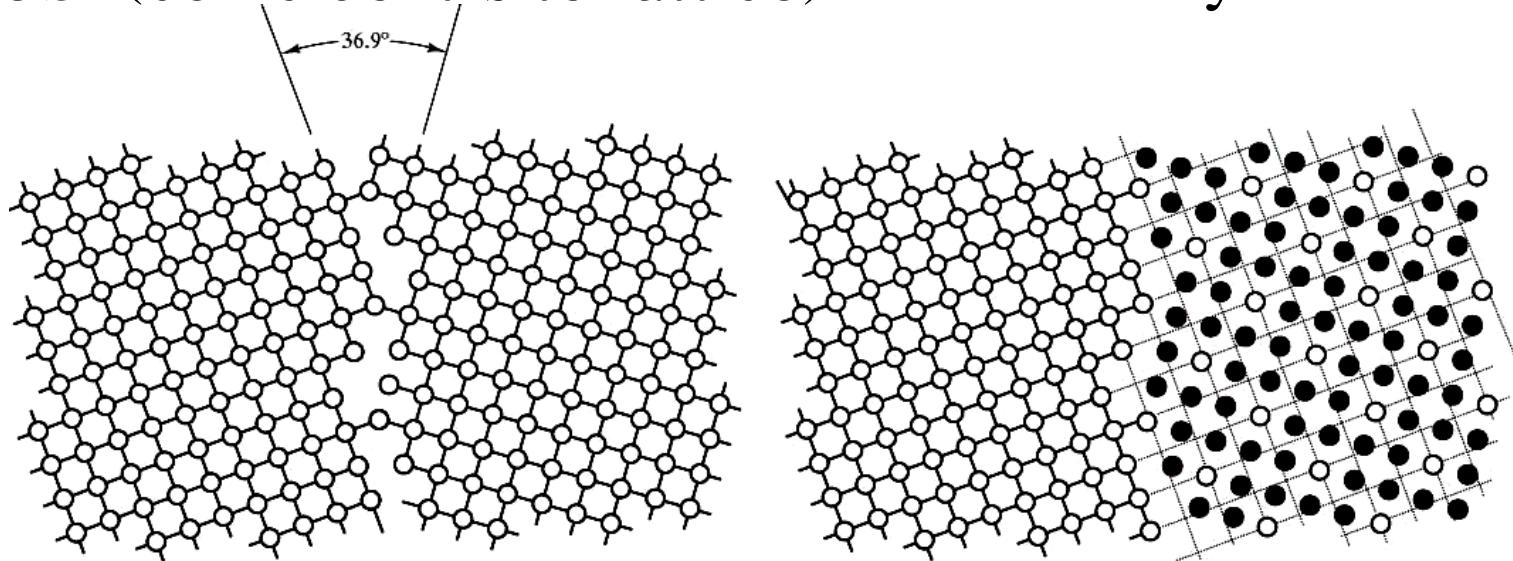


Low Angle Grain Boundary



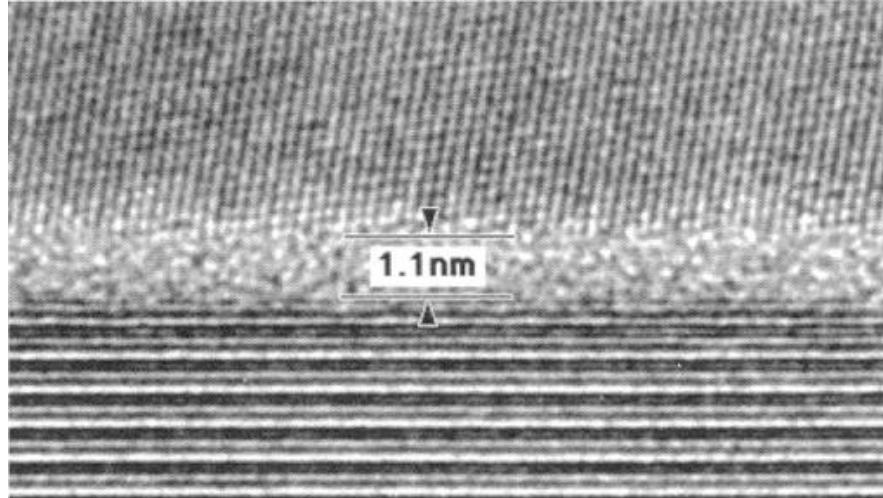
High Angle Grain Boundary

- CSL(coincident site lattice)- $\Sigma 5$ boundary

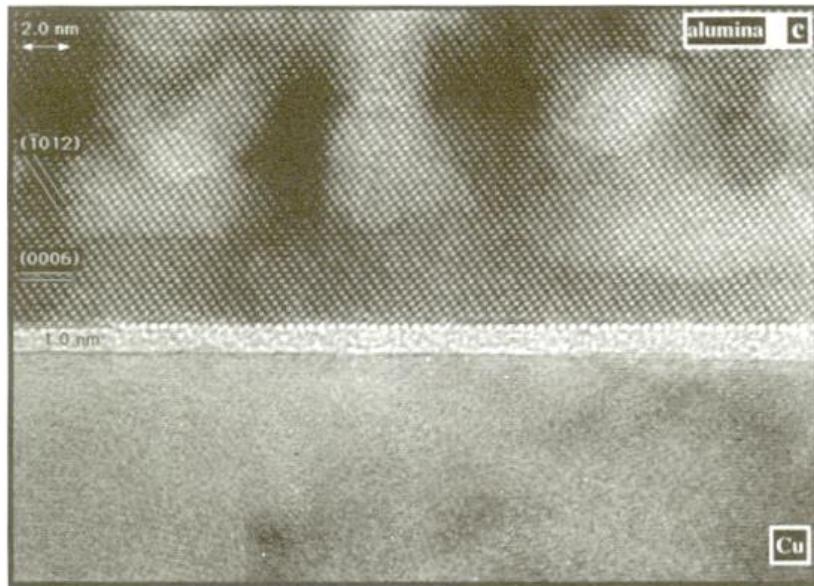


$\Sigma 5$ boundary
for an FCC metal

Grain Boundary

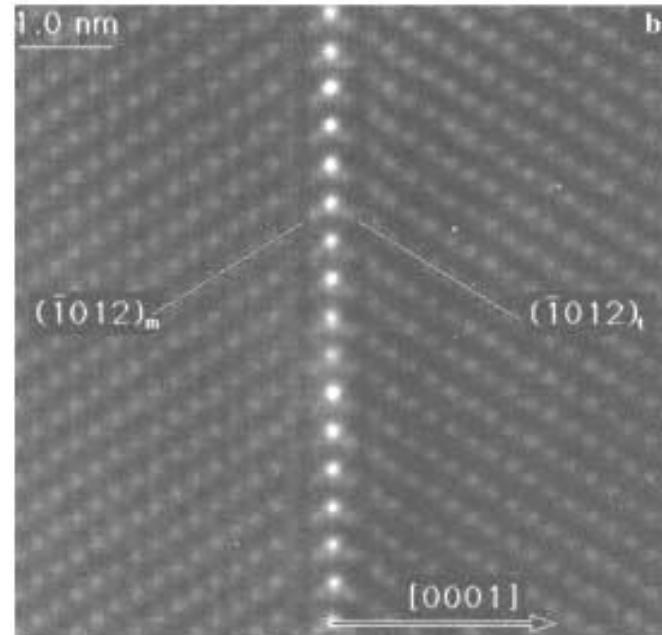


amorphous glassy In-Si₃N₄

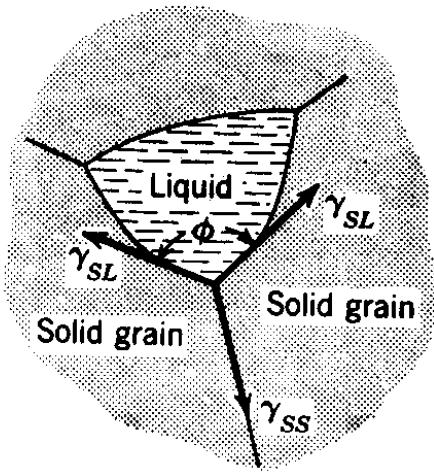


Si-Ca glass in alumina

Ca segregation

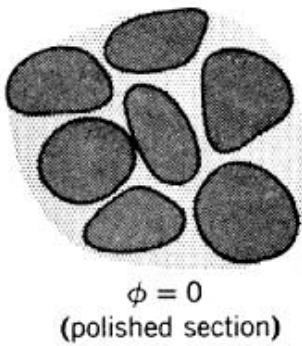


Grain Boundary

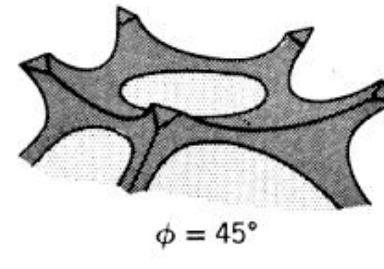


$$\gamma_{SS} = 2\gamma_{SL} \cos \frac{\phi}{2}$$

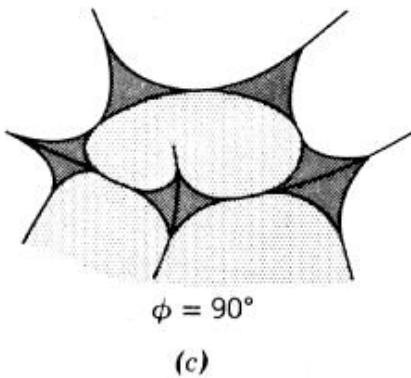
ϕ : dihedral angle



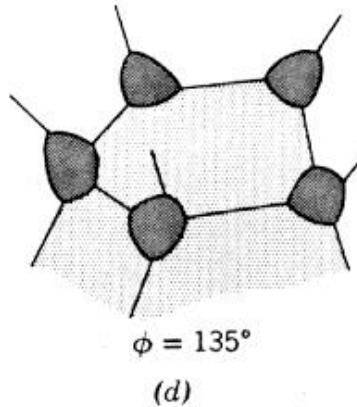
(a)



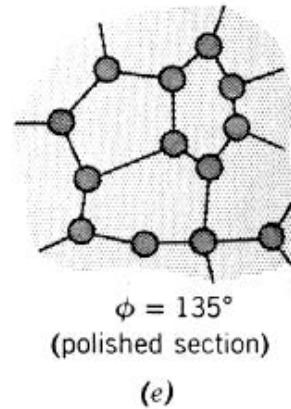
(b)



(c)

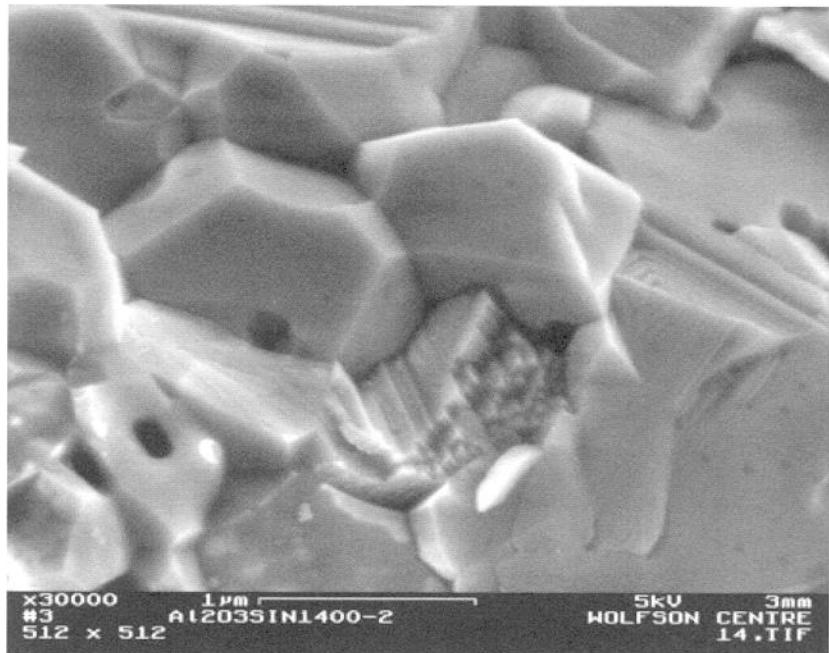


(d)

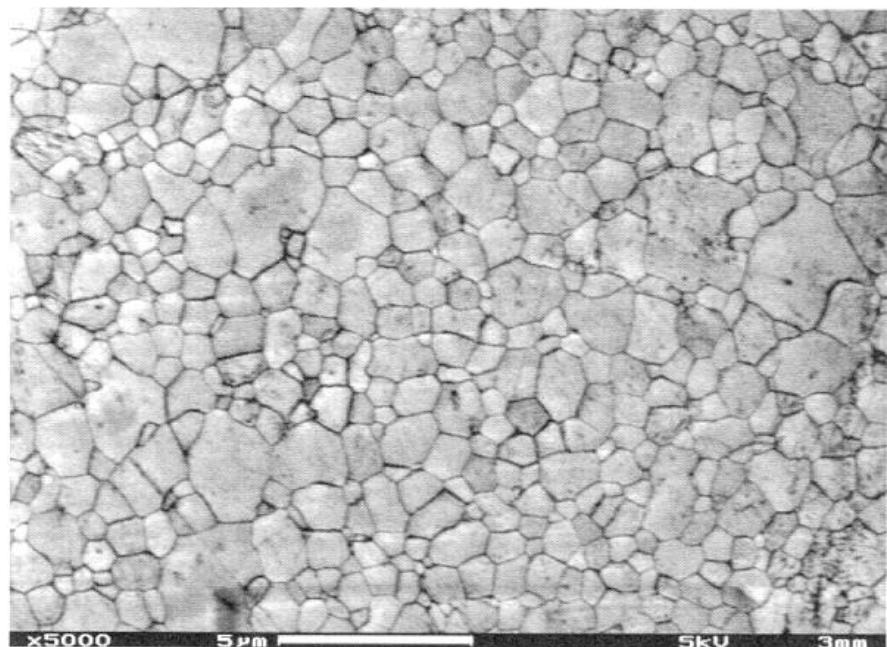


(e)

Observation of Grain Boundary



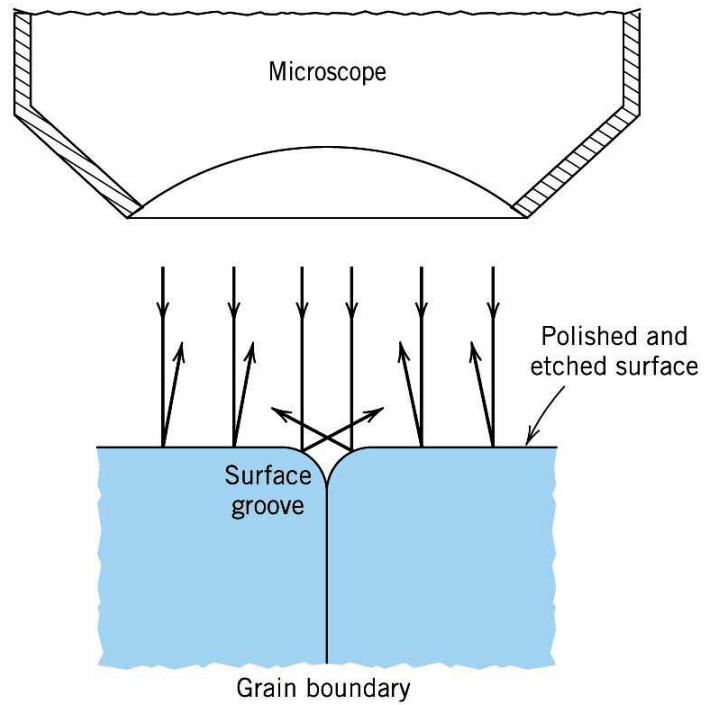
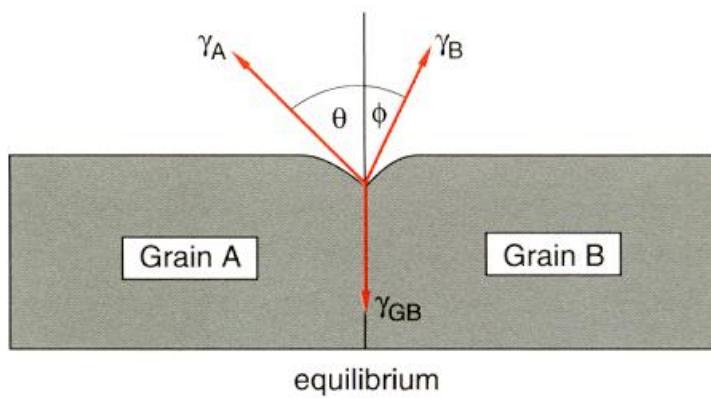
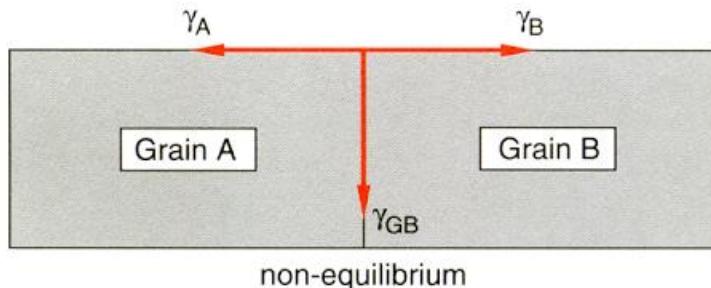
fracture surface of alumina



thermally etched alumina

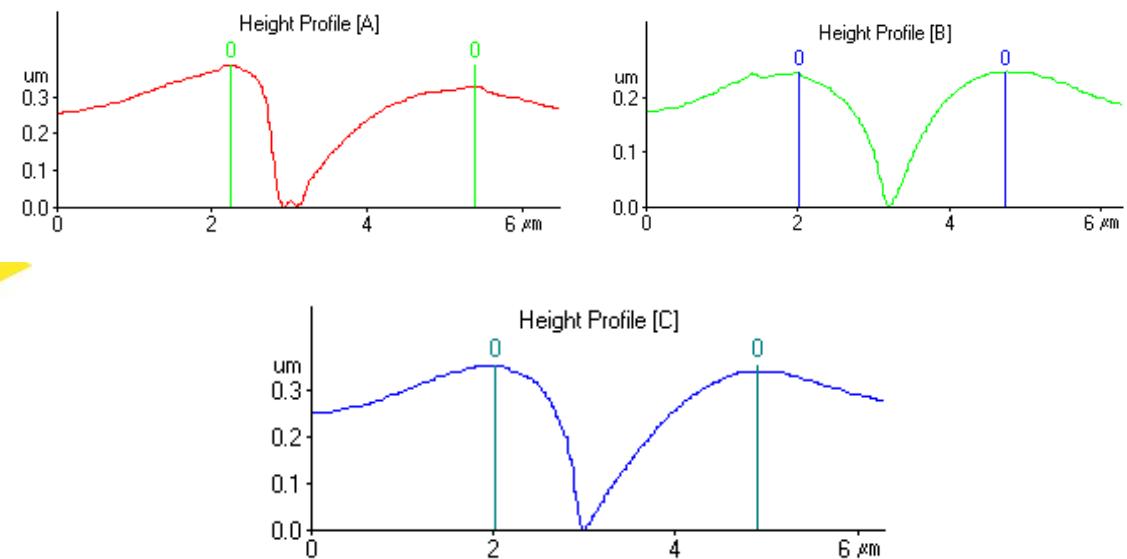
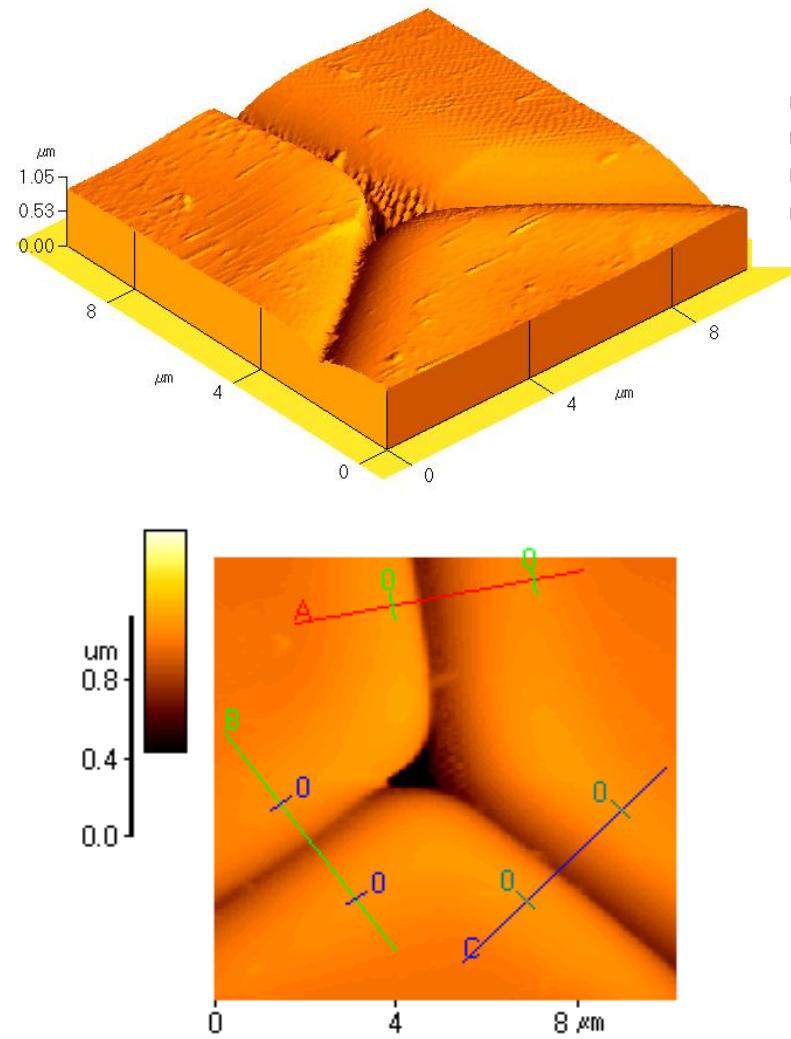
Observation of Grain Boundary

- etching – chemical
thermal – groove



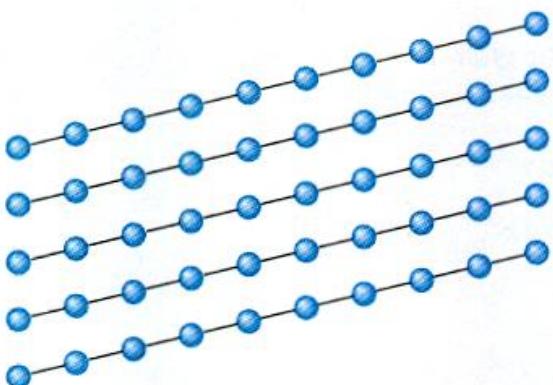
Thermal Grooving

- alumina

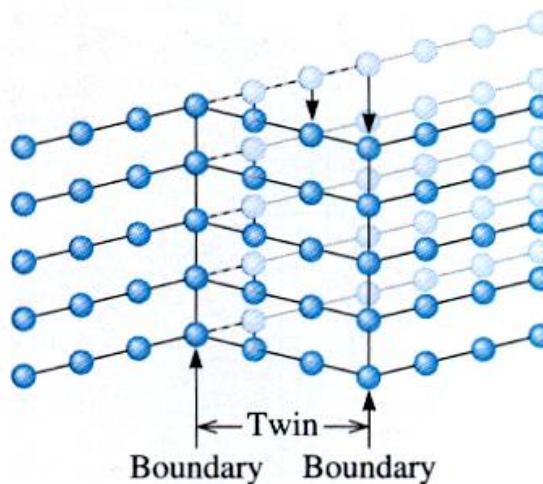


Line	Height	Distance	Angle
[A]	0: 581 Å	0: 3.16 μm	0: 1.1 °
[B]	0: 60.5 Å	0: 2.72 μm	0: 0.1 °
[C]	0: 124 Å	0: 2.87 μm	0: 0.2 °

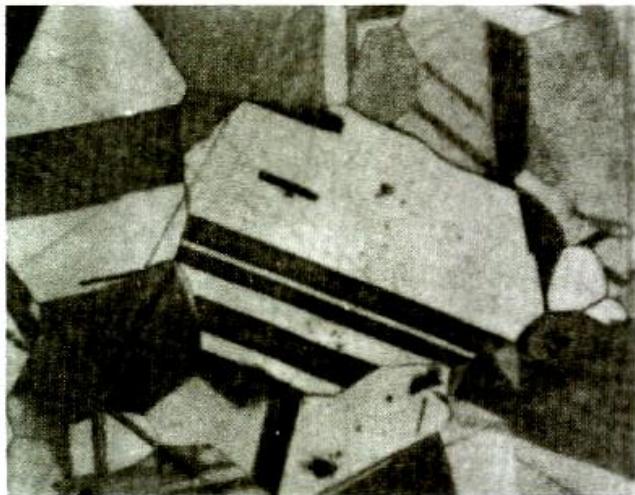
Twin Boundary



(a)

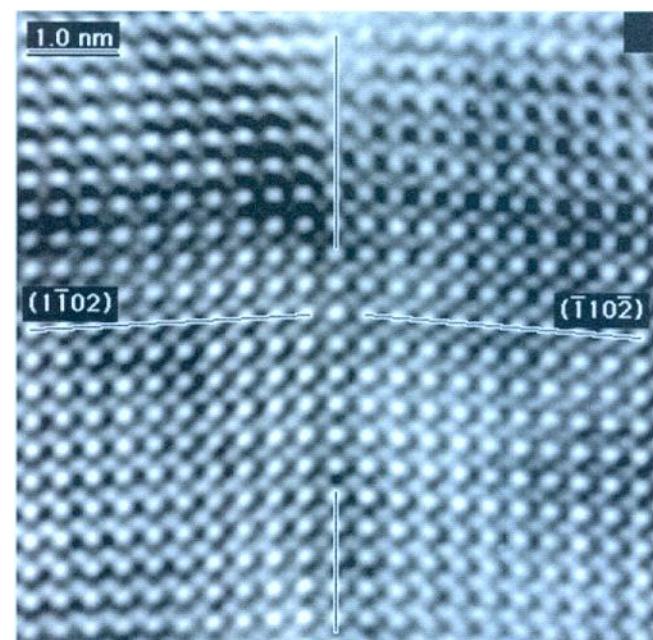


(b)



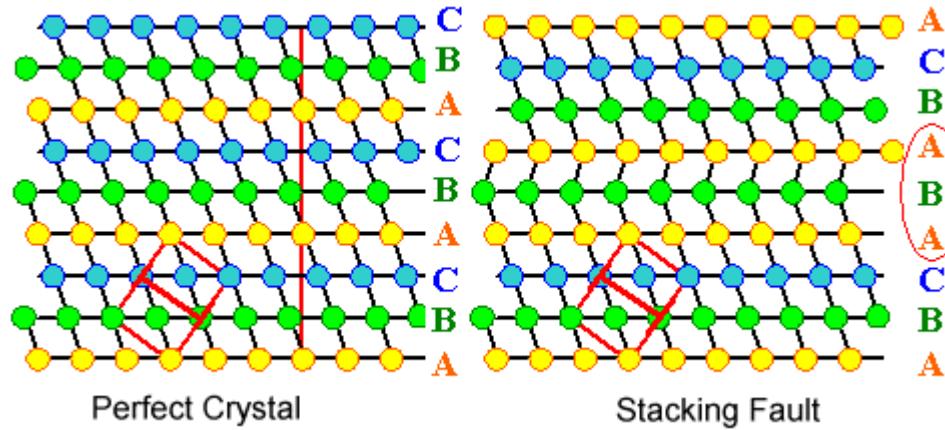
(c)

Figure 4-20 Application of a stress to the perfect crystal (a) may cause a displacement of the atoms, (b) causing the formation of a twin. Note that the crystal has deformed as a result of twinning. (c) A micrograph of twins within a grain of brass ($\times 250$).

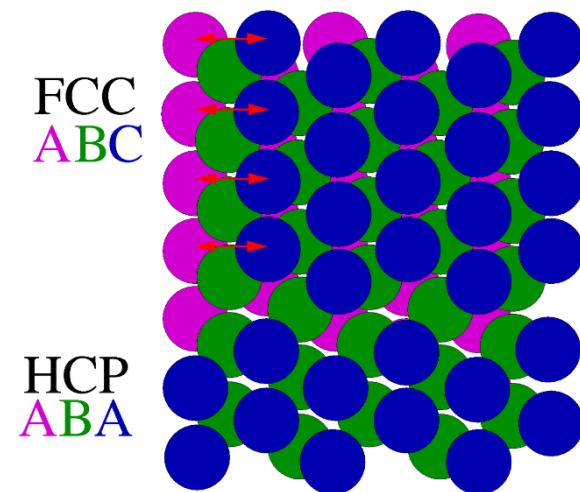


rhombohedral twin
in alumina

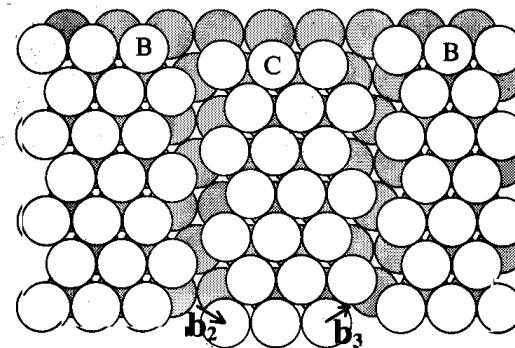
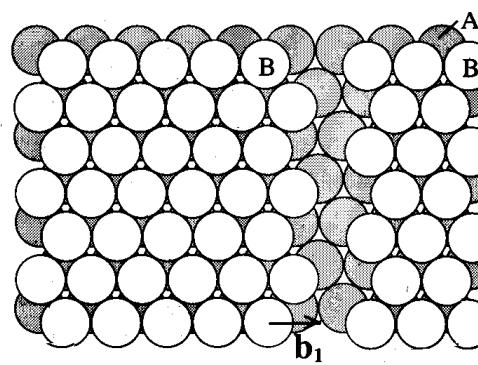
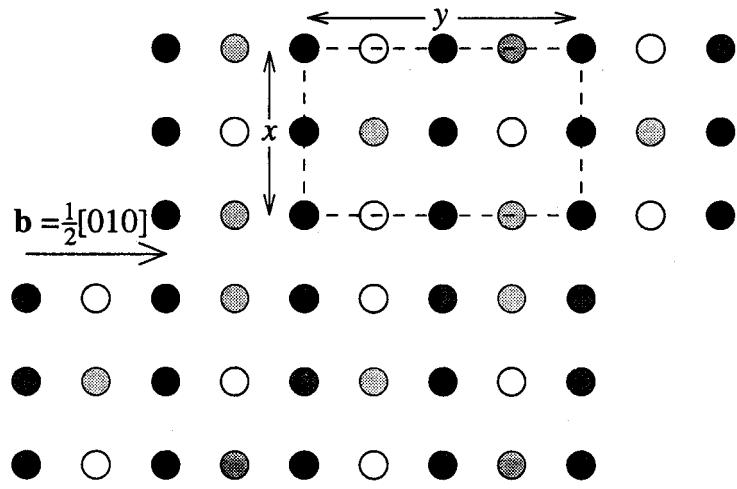
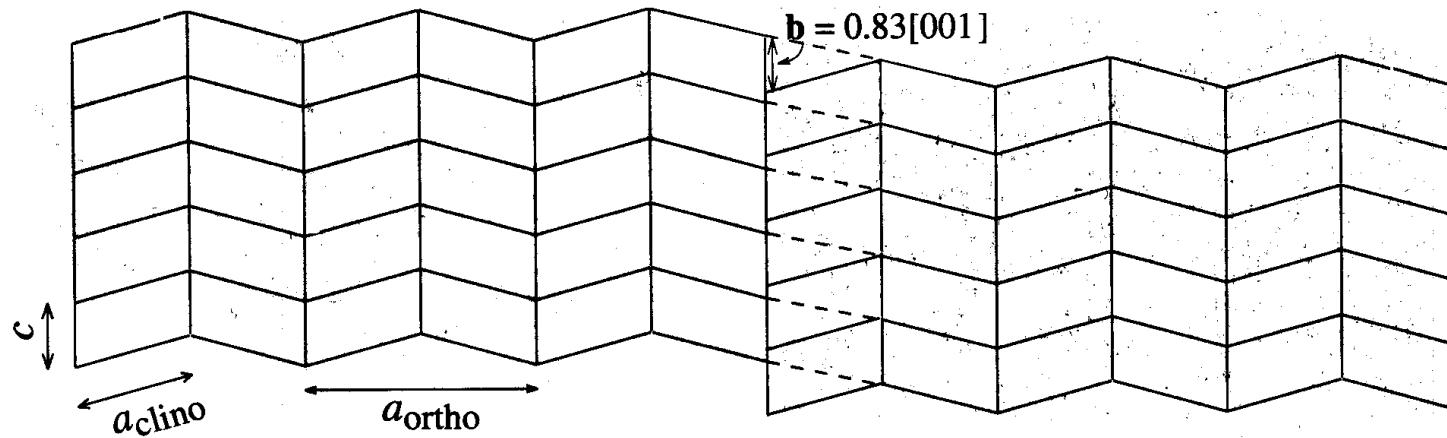
Stacking Fault

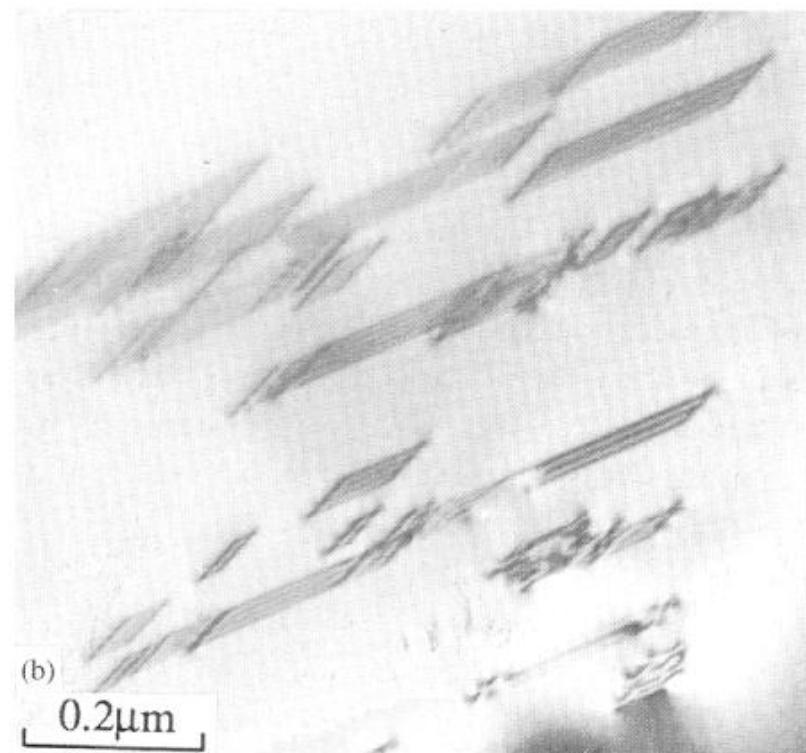
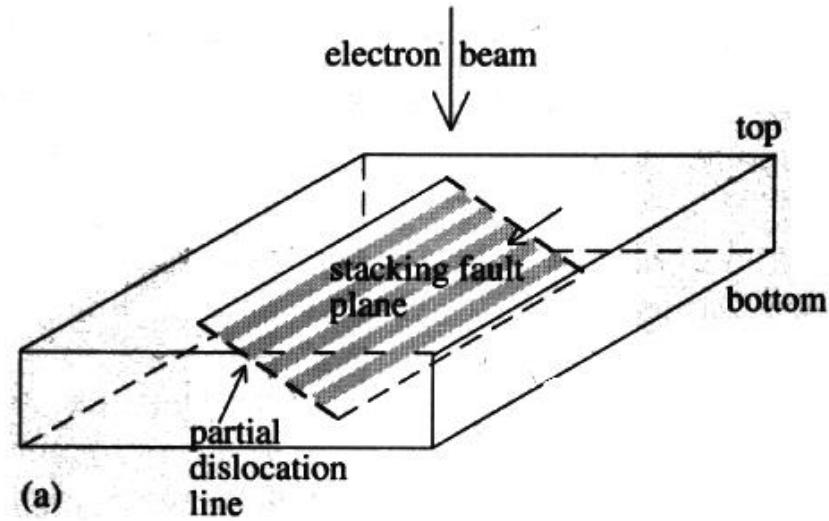
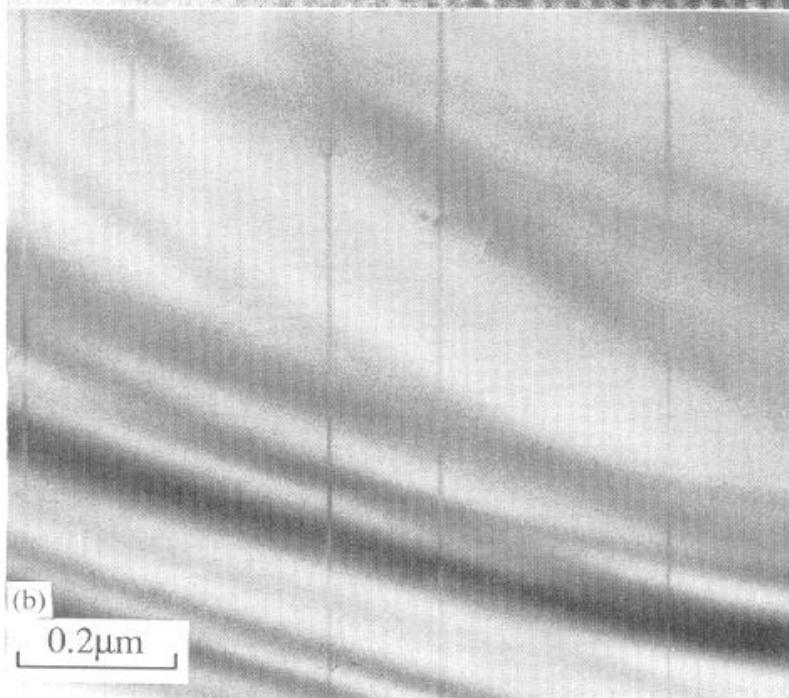
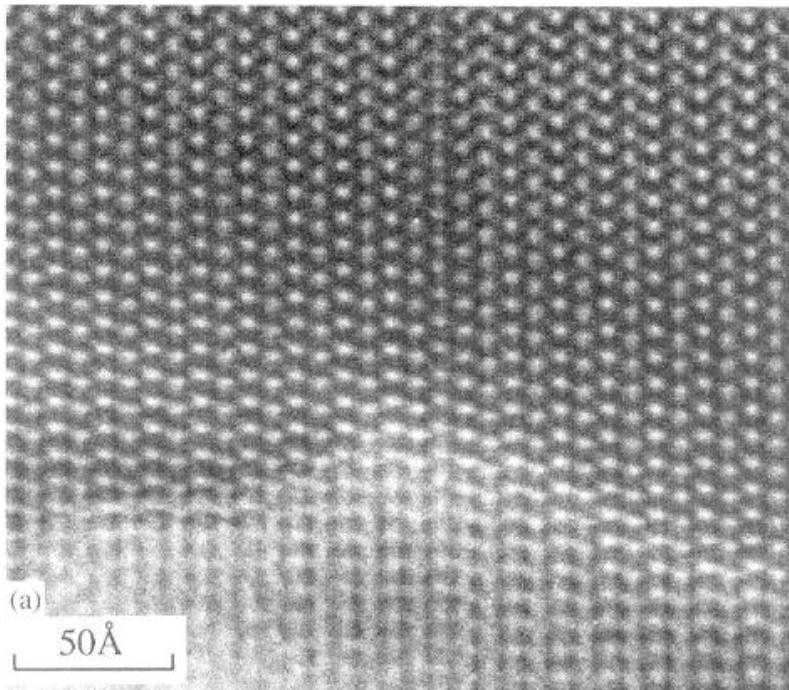


Perfect and faulted stacking sequence for an fcc crystal



Stacking Fault





Domain Boundary

- domain- a small region of the material in which the direction of electric polarization or magnetization remains the same
- ex) ferromagnets (Fe, Co, Ni) ferroelectric (PZT, BaTiO₃)

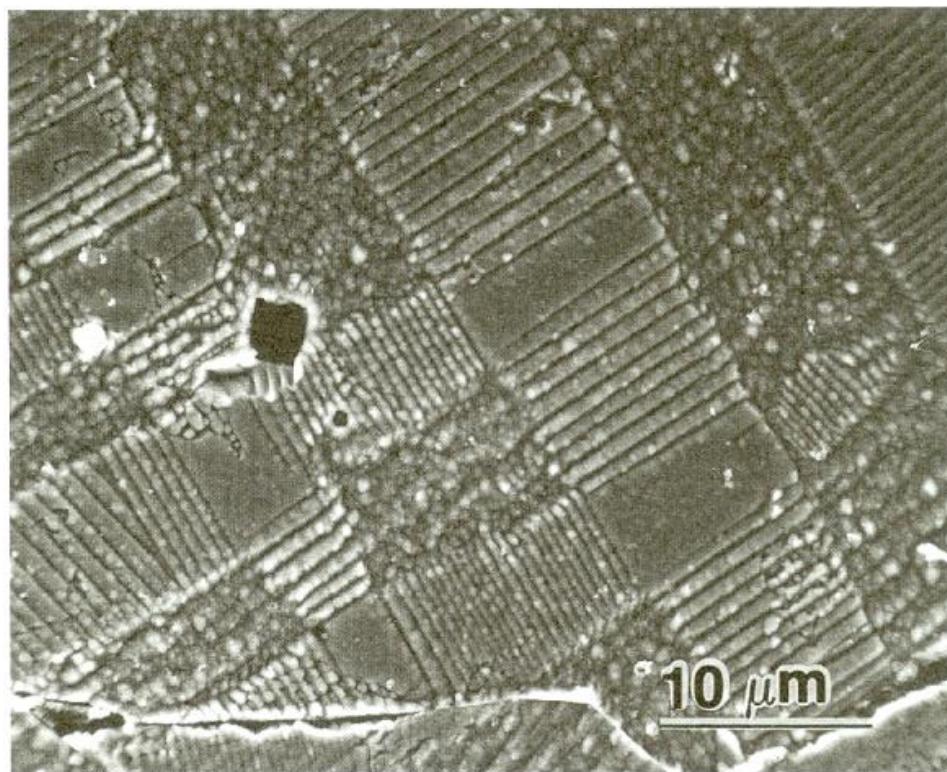


Figure 4-21 Domains in ferroelectric barium titanate. (*Courtesy of Dr. Rodney Roseman, University of Cincinnati.*) Similar domain structures occur in ferromagnetic and ferrimagnetic materials.